PAQ50S48-*

EVALUATION DATA

型式データ

DWG.No. C165-53-01B

DENSEI-LAMBDA

INDEX

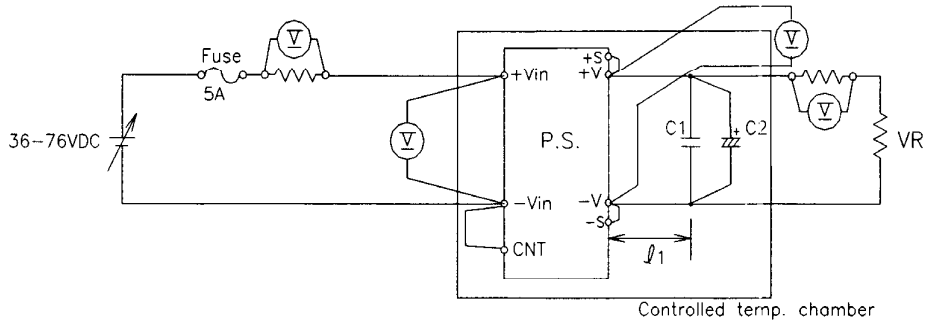
使用記号 Terminology used

	Definition	
Vin	..... 入力電圧	Input Voltage
Vout	..... 出力電圧	Output Voltage
VCNT	..... CNT電圧	CNT Voltage
Iin	..... 入力電流	Input Current
Iout	..... 出力電流	Output Current
Ta	..... 周囲温度	Ambient Temperature

1. 測定方法　Evaluation Method

1. 1 測定回路　Circuits used for determination

(1) 静特性　Steady state data



C1:　1uF Ceramic Capacitor
C2: 10uF Tantalum Capacitor

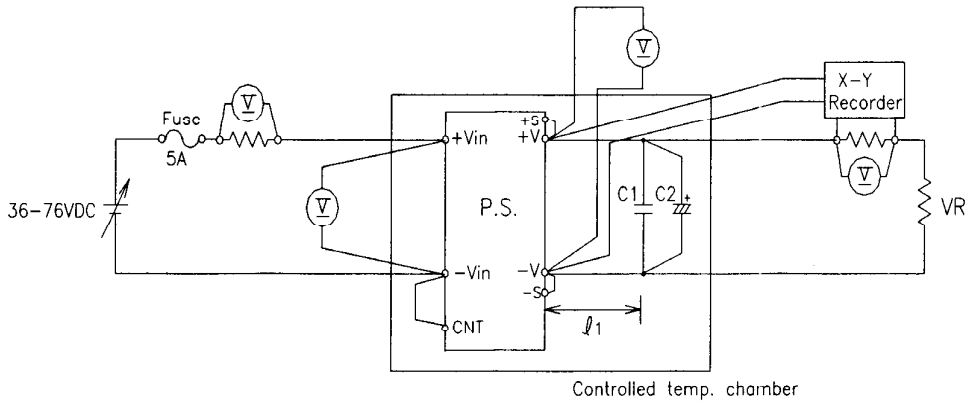
ℓ1 : 50mm

(2) 通電ドリフト　Warm up voltage drift characteristics

静特性と同じ

Same as Steady state data

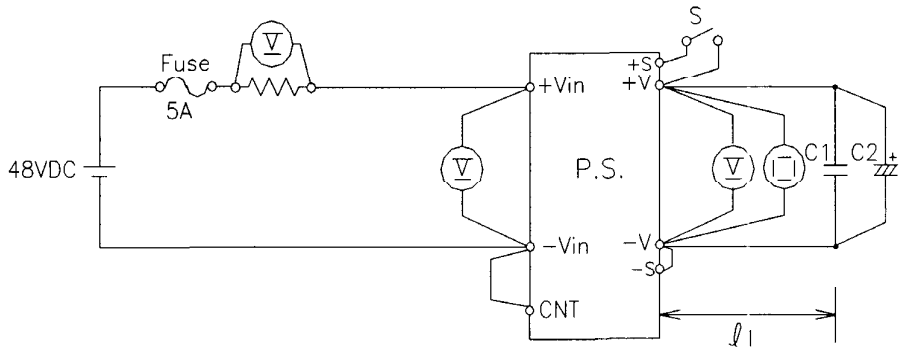
(3) 過電流保護特性　Over current protection (OCP) characteristics



C1:　1uF Ceramic Capacitor
C2: 10uF Tantalum Capacitor

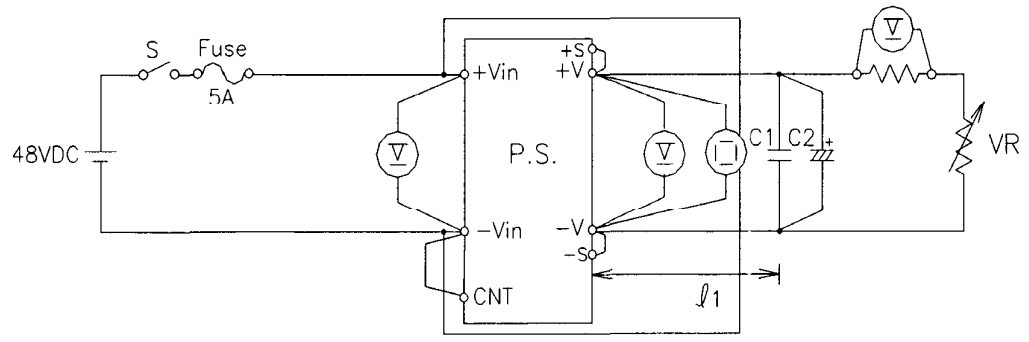
ℓ1 : 50mm

(4) 過電圧保護特性　Over voltage protection (OVP) characteristics



C1:　1uF Ceramic Capacitor　　ℓ1 : 50mm
C2: 10uF Tantalum Capacitor

(5) 出力立ち上がり特性　Output rise characteristics



C1:　1uF Ceramic Capacitor　　ℓ1 : 50mm
C2: 10uF Tantalum Capacitor

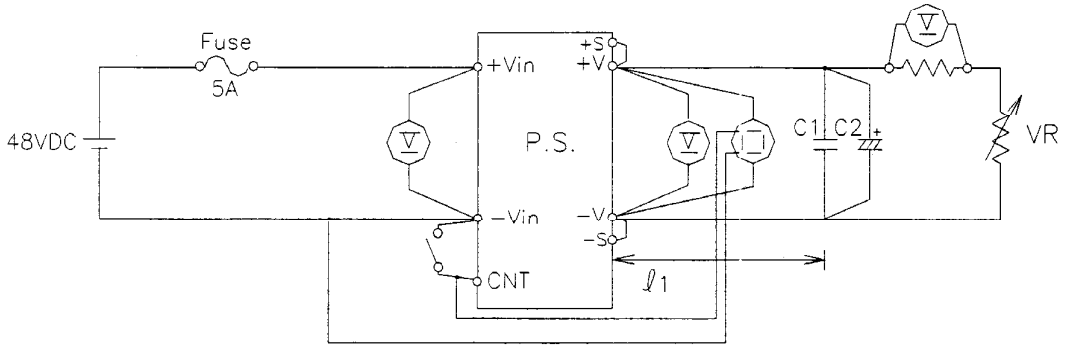
(6) 出力立ち下がり Output fall characteristics

出力立ち上がり特性と同じ

Same as output rise characteristics

(7) 出力立ち上がり特性 （ ON/OFFコントロール時)

Output rise characteristics with ON/OFF CONTROL



C1: 1uF Ceramic Capacitor
C2: 10uF Tantalum Capacitor

ℓ1 : 50mm

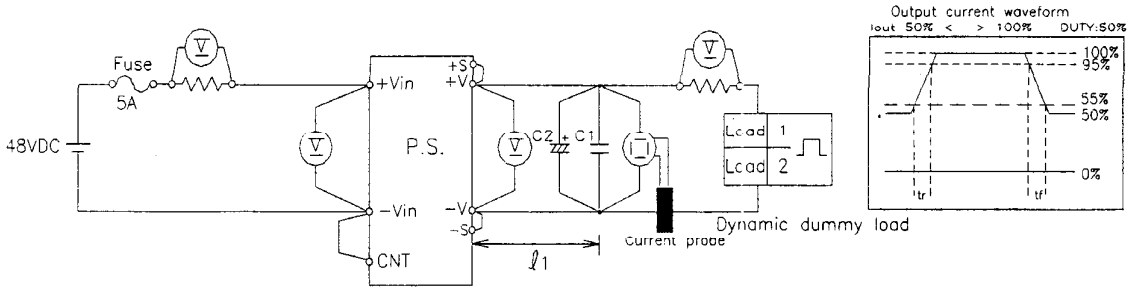
(8) 出力立ち下がり特性 （ ON/OFFコントロール時)

Output fall characteristics with ON/OFF CONTROL

出力立ち上がり特性（ ON/OFFコントロール時）と同じ

Same as output rise characteristics with ON/OFF CONTROL

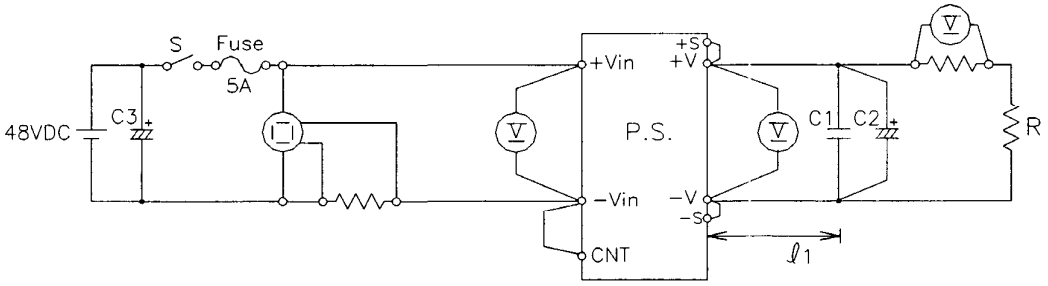
(9) 過渡応答(負荷急変)特性 Dynamic load response characteristics



C1: 1uF Ceramic Capacitor
C2: 10uF Tantalum Capacitor

ℓ1 : 50mm

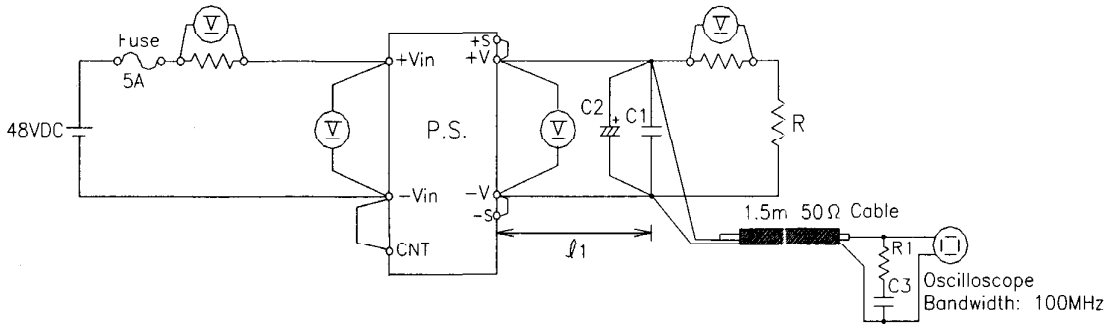
(10) 入力サージ電流（突入電流）特性　Inrush current characteristics



C1:　1uF Ceramic Capacitor
C2:　10uF Tantalum Capacitor

ℓ1 :　50mm

(11) 出力リップル、ノイズ波形　Output ripple and noise waveform

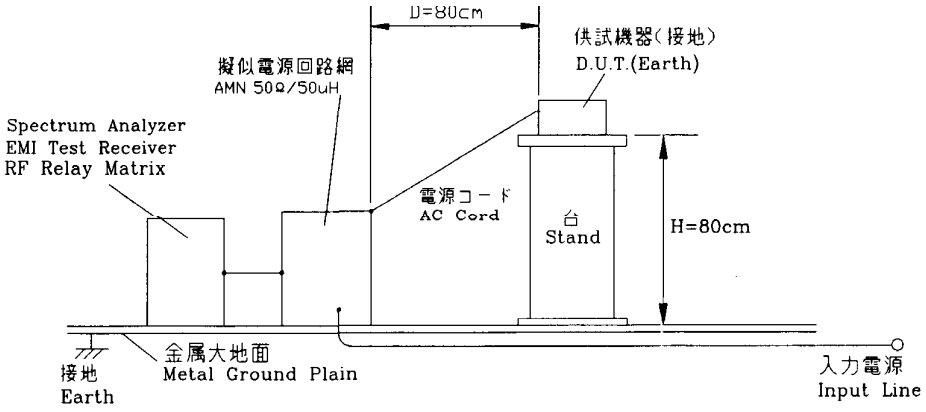


C1:　1uF Ceramic Capacitor
C2:　10uF Tantalum Capacitor
C3:　4700pF Film Capacitor

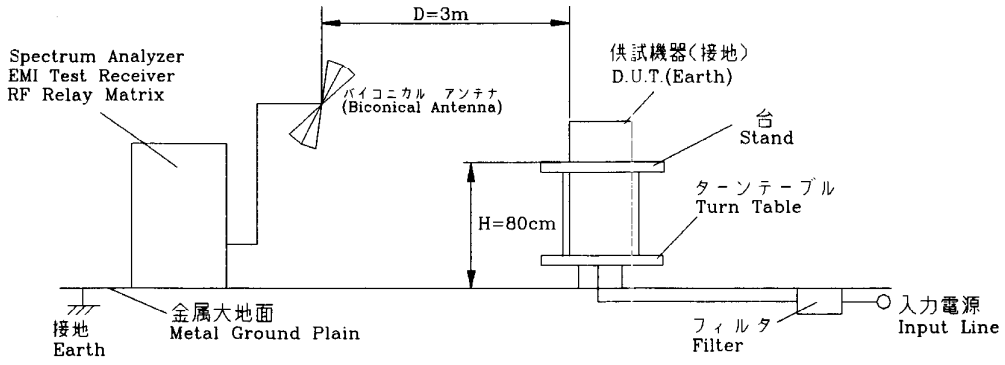
R1:　50 Ω
ℓ1 :　50mm

(12) ＥＭＩ特性　Electro-Magnetic Interference characteristics

(a)　雑音端子電圧（帰還ノイズ）　Conducted Emission Noise

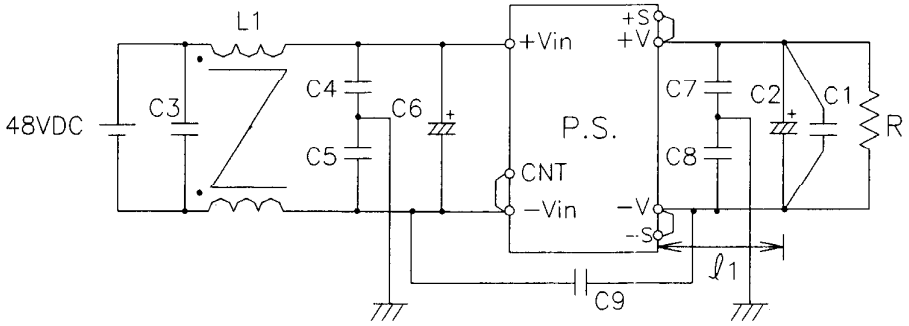


(b) 雑音電界強度（輻射ノイズ） Radiated Emission Noise



(1) VCC class A 対応対応アプリケーションシステム

VCCI class A application system



L1 : 1mH
C1 : 1uF Ceramic Capacitor
C2 : 10uF Tantalum Capacitor
C3 : 1uF Film Capacitor
C4,C5 : 0.068uF Film Capacitor
C6 : 470uF Electrolytic Capacitor
C7,C8 : 0.033uF Film Capacitor
C9 : 2200pF Ceramic Capacitor
ℓ1 : 50mm

1.2 使用測定機器　List of equipment used

	EQUIPMENT USED	MANUFACTURER	MODEL NO.
1	OSCILLO SCOPE	HITACHI DENSHI	V-1100A
2	DIGITAL STORAGE OSCILLOSCOPE	IWATSU-LECROY	LT364L
3	DIGITAL MULTIMETER	ADVANTEST	R6341A
4	DIGITAL POWER METER	YOKOGAWA ELECT.	WT110
5	CURRENT PROBE/AMPLIFIER	TEKTRONIX	A6303/AM503
6	SHUNT REGISTER	YOKOGAWA ELECT.	2215
7	X-Y RECORDER	GRAPHTEC	WX4309
8	CONTROLLED TEMP. CHANBER	TABAI ESPEC	SH-240
9	SPECTRUM ANALYZER	ROHDE & SCHWARZ	FSA
10	EMI TEST RECEIVER	ROHDE & SCHWARZ	ESHS10
11	EMI TEST RECEIVER	ROHDE & SCHWARZ	ESVS10
12	RF RELAY MATRIX	ROHDE & SCHWARZ	PSU
13	AMN	KYORITU DENSHI	KNW-242
14	ANTENNA(BICONICAL ANTENNA)	SCHWARZBECK	BBA9106
15	DYNAMIC DUMMY LOAD	TAKASAGO	FK-1000L
16	AC POWER SUPPLY	KIKUSUI	PCR4000L

2. 特性データ
2. 1 静特性　　Steady state data
(1) 入力、負荷、温度変動　Regulation - line and load, temperature drift

1.8V

1. Regulation - line and load　　condition Ta : 25℃
Air Velocity : 2m/s

Iout \ Vin	36VDC	48VDC	76VDC	line regulation	
0%	1.7913V	1.7913V	1.7912V	0.1mV	0.006%
50%	1.7913V	1.7913V	1.7912V	0.1mV	0.006%
100%	1.7913V	1.7913V	1.7910V	0.3mV	0.017%
load	0.0mV	0.0mV	0.2mV		
regulation	0.000%	0.000%	0.011%		

2. Temperature drift　　conditions Vin : 48VDC
Iout : 100%
Air Velocity : 2m/s

Ta	-40℃	25℃	85℃	temperature stability	
Vout	1.7979V	1.7913V	1.7881V	9.8mV	0.544%

3.3V

1. Regulation - line and load　　condition Ta : 25℃
Air Velocity : 2m/s

Iout \ Vin	36VDC	48VDC	76VDC	line regulation	
0%	3.3037V	3.3036V	3.3037V	0.1mV	0.003%
50%	3.3038V	3.3037V	3.3035V	0.3mV	0.009%
100%	3.3038V	3.3037V	3.3034V	0.4mV	0.012%
load	0.1mV	0.1mV	0.3mV		
regulation	0.003%	0.003%	0.009%		

2. Temperature drift　　conditions Vin : 48VDC
Iout : 100%
Air Velocity : 2m/s

Ta	-40℃	25℃	85℃	temperature stability	
Vout	3.3062V	3.3037V	3.2935V	12.7mV	0.385%

2. 特性データ
2.1 静特性　　Steady state data
(1) 入力、負荷、温度変動　Regulation - line and load, temperature drift

5V

1. Regulation - line and load　　condition Ta : 25℃
Air Velocity : 2m/s

Iout \ Vin	36VDC	48VDC	76VDC	line regulation	
0%	4.9971V	4.9977V	4.9968V	0.9mV	0.018%
50%	4.9975V	4.9978V	4.9971V	0.7mV	0.014%
100%	4.9972V	4.9972V	4.9961V	1.1mV	0.022%
load	0.4mV	0.6mV	1.0mV		
regulation	0.008%	0.012%	0.020%		

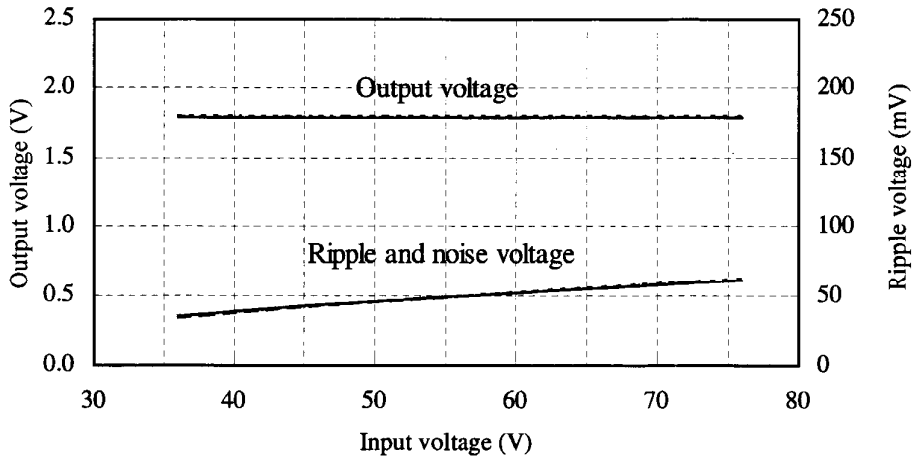
2. Temperature drift　　conditions Vin : 48VDC
Iout : 100%
Air Velocity : 2m/s

Ta	-40℃	25℃	85℃	temperature stability	
Vout	5.0064V	4.9972V	4.9808V	25.6mV	0.512%

2.1 (2) 出力電圧、リップル電圧対入力電圧
Output voltage and ripple voltage vs input voltage

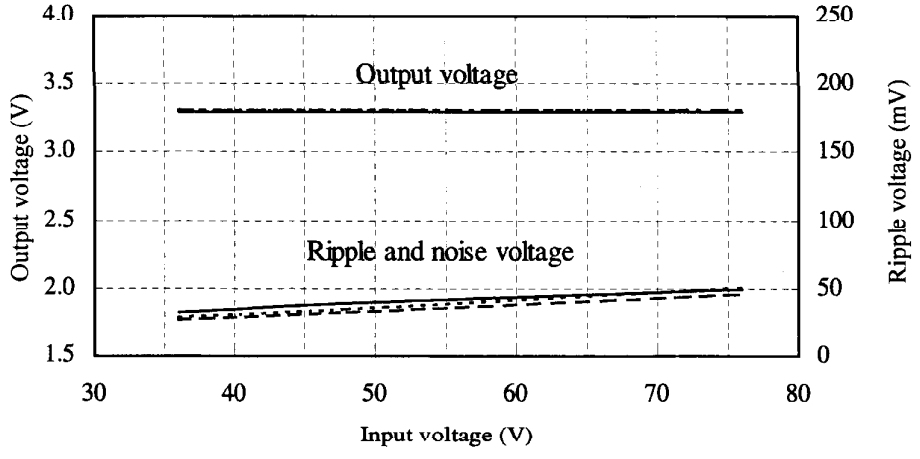
Conditions Iout : 100 %
Ta : -40 ℃ -------
25 ℃ —·—·—
85 ℃ ———
Air Velocity : 2 m/s

1.8V



Ta : -40 ℃ -------
25 ℃ —·—·—
85 ℃ ———
Air Velocity : 2 m/s

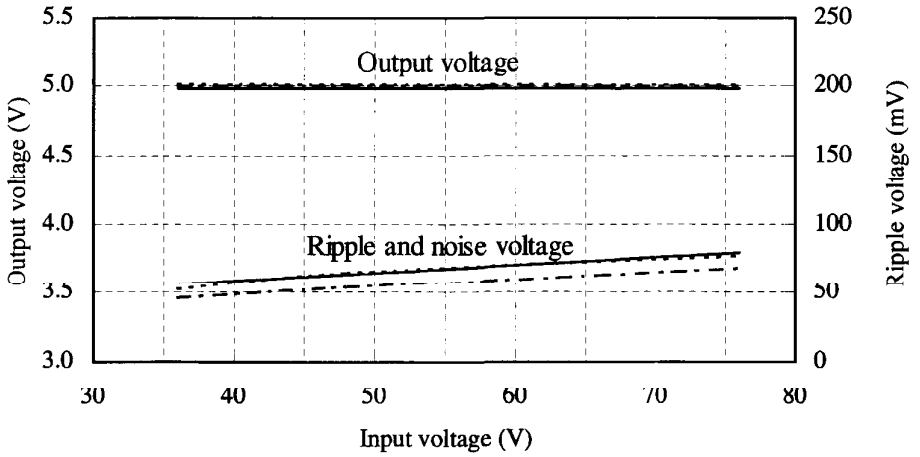
3.3V



2. 1 (2) 出力電圧、リップル電圧対入力電圧
Output voltage and ripple voltage vs input voltage

Conditions Iout : 100 %
Ta : -40 ℃ -------
25 ℃ -.-.-.-
85 ℃ ———
Air Velocity : 2 m/s

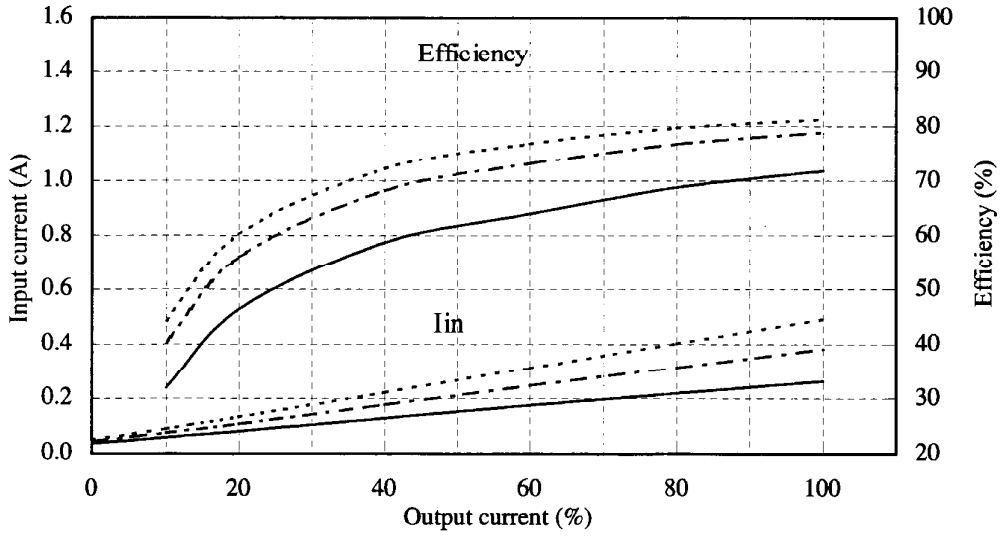
5V



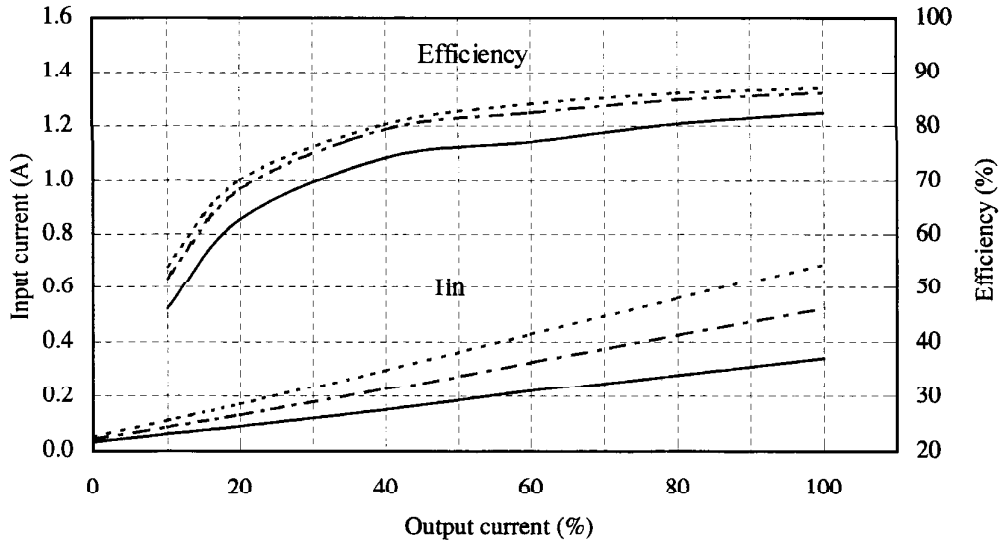
2.1 (3) 効率、入力電流対出力電流
Efficiency and input current vs output current

Conditions Vin : 36 VDC -------
: 48 VDC -.-.-.-
: 76 VDC ———
Ta : 25 ℃
Air Velocity : 2 m/s

1.2V



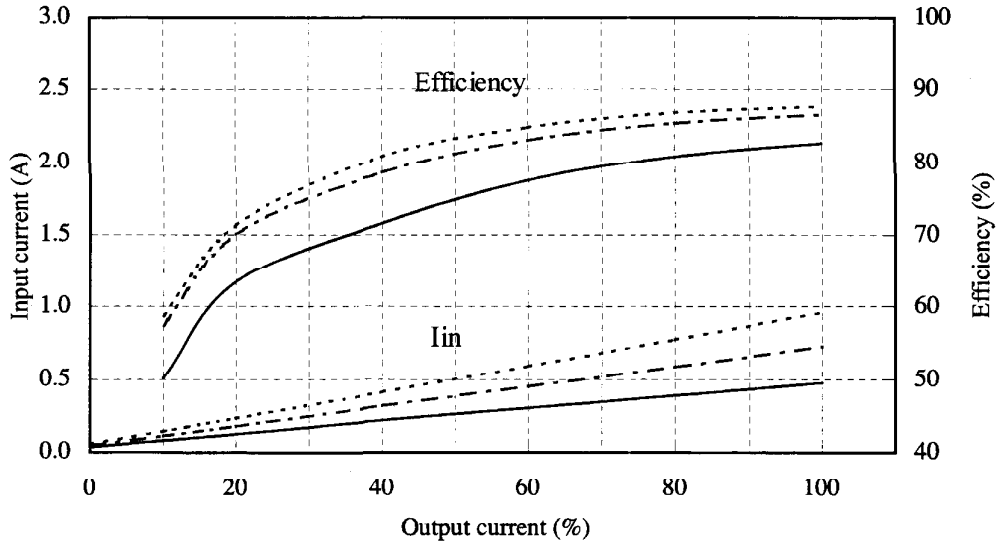
1.8V



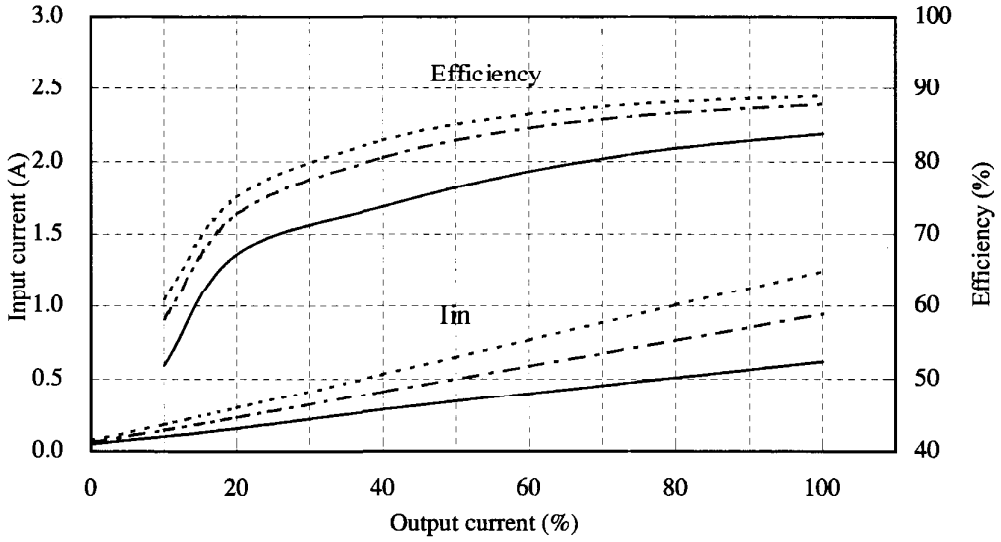
2.1 (3) 効率、入力電流対出力電流
Efficiency and input current vs output current

Conditions Vin : 36 VDC -------
: 48 VDC -·-·-·-
: 76 VDC ———
Ta : 25 ℃
Air Velocity : 2 m/s

2.5V



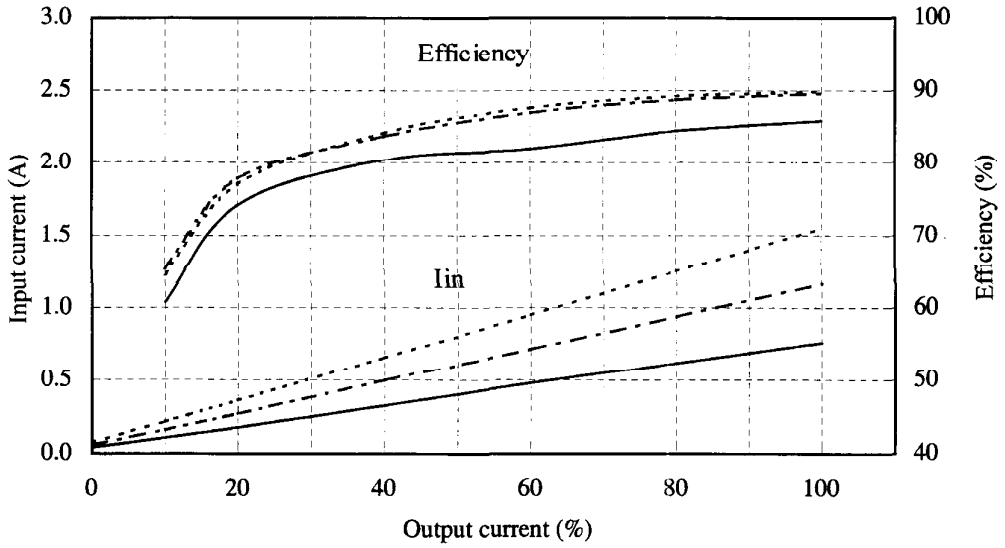
3.3V



2.1 (3) 効率、入力電流対出力電流
Efficiency and input current vs output current

Conditions Vin : 36 VDC -------
: 48 VDC —·—·—
: 76 VDC ———
Ta : 25 ℃
Air Velocity : 2 m/s

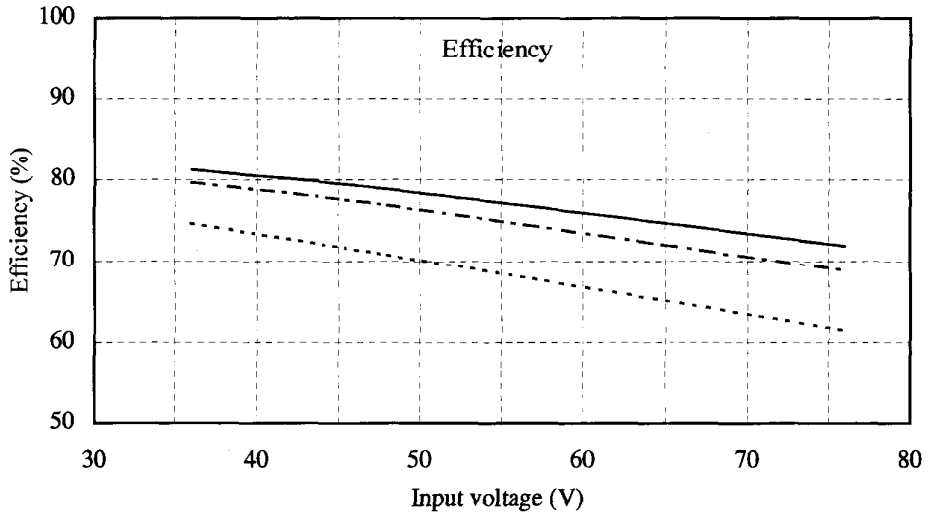
5V



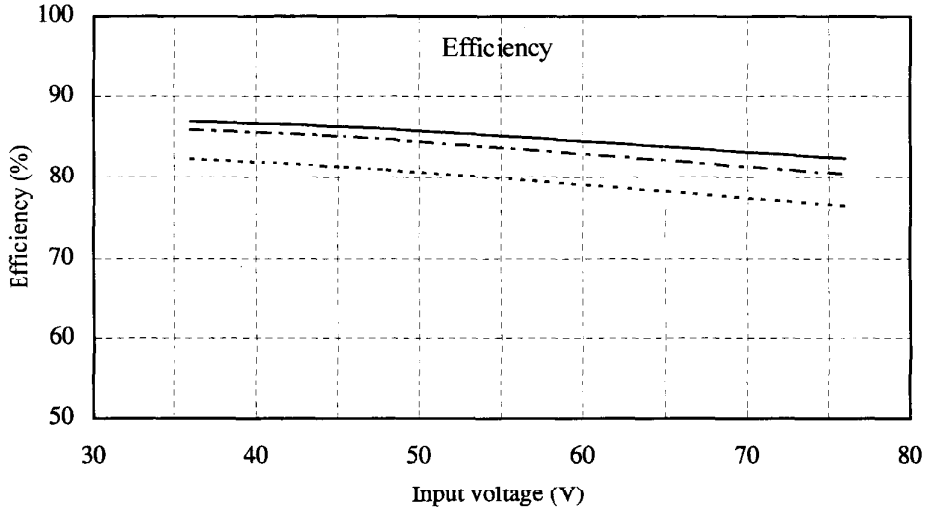
2.1 (4) 効率対入力電圧
Efficiency vs input voltage

Conditions Ta : 25 ℃
Iout : 50 % -------
80 % -.-.-.-
100 % ———
Air Velocity : 2 m/s

1.2V



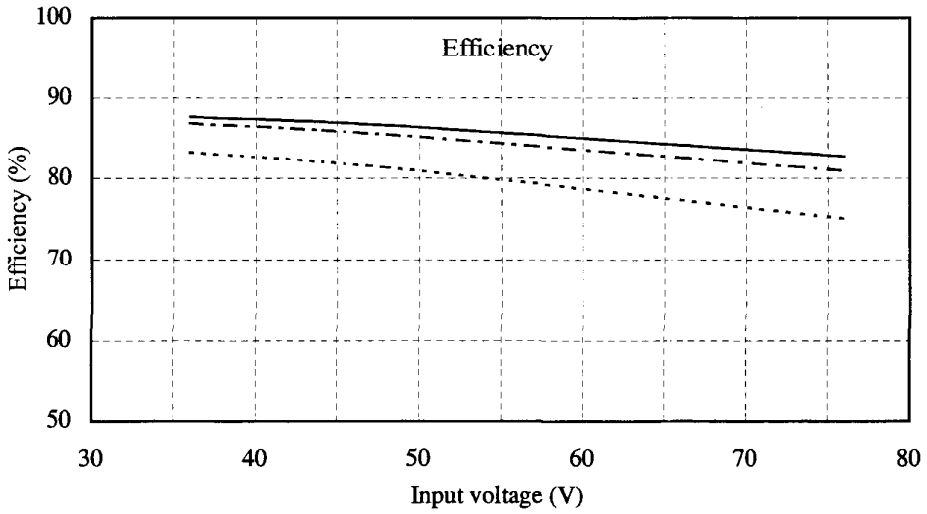
1.8V



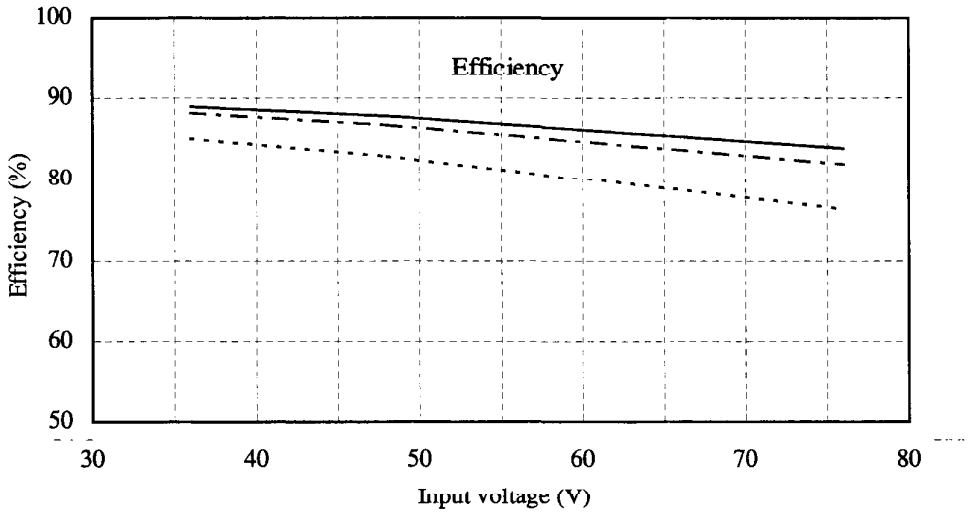
2.1 (4) 効率対入力電圧
Efficiency vs input voltage

Conditions Ta : 25 ℃
Iout : 50 % -------
80 % -.-.-.-
100 % ———
Air Velocity : 2 m/s

2.5V



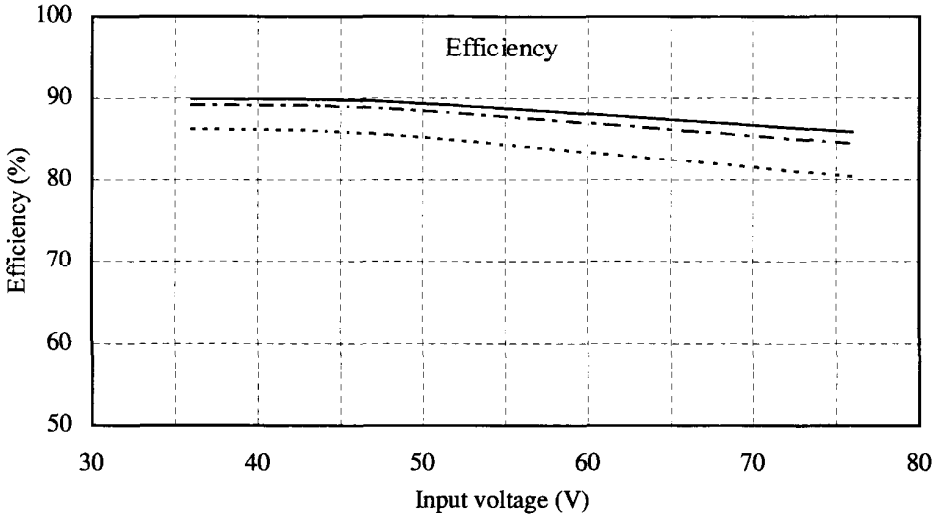
3.3V



2.1 (4) 効率対入力電圧
Efficiency vs input voltage

Conditions Ta : 25 ℃
Iout : 50 % -------
80 % -·-·-·-
100 % ———
Air Velocity : 2 m/s

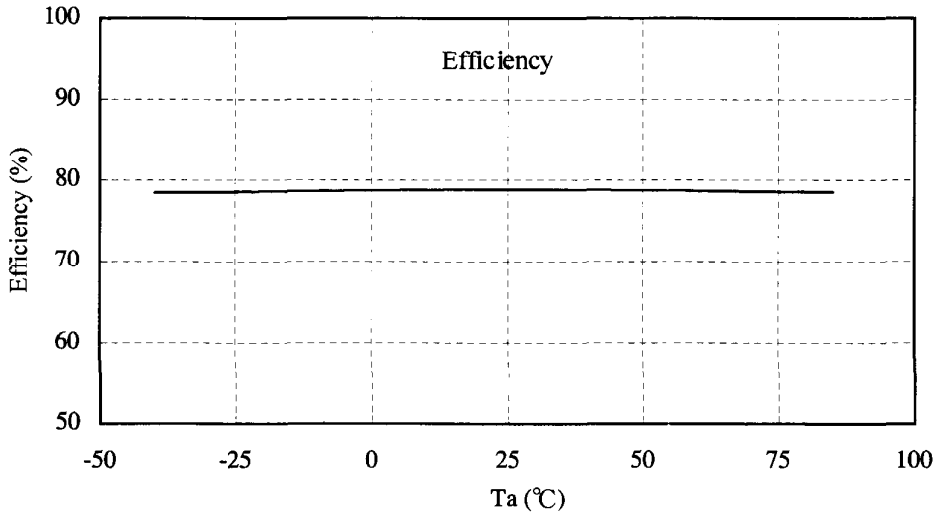
5V



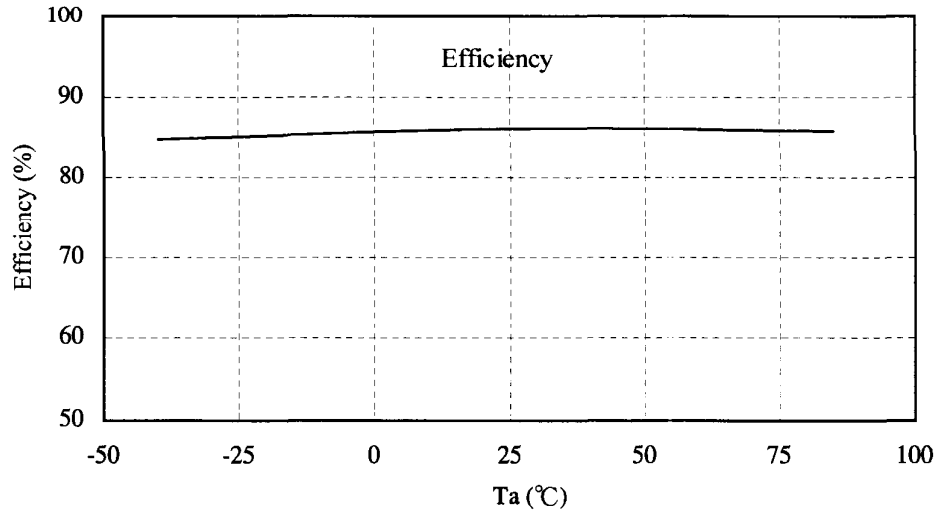
2. 1 (5) 効率対周囲温度
Efficiency vs ambient temperature

Conditions Vin : 48 VDC
Iout : 100 %
Air Velocity : 2 m/s

1.2V



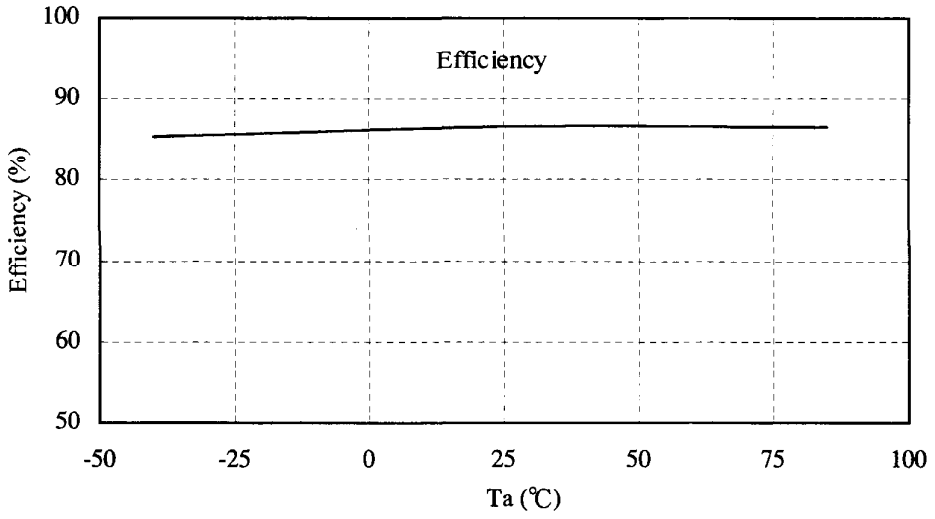
1.8V



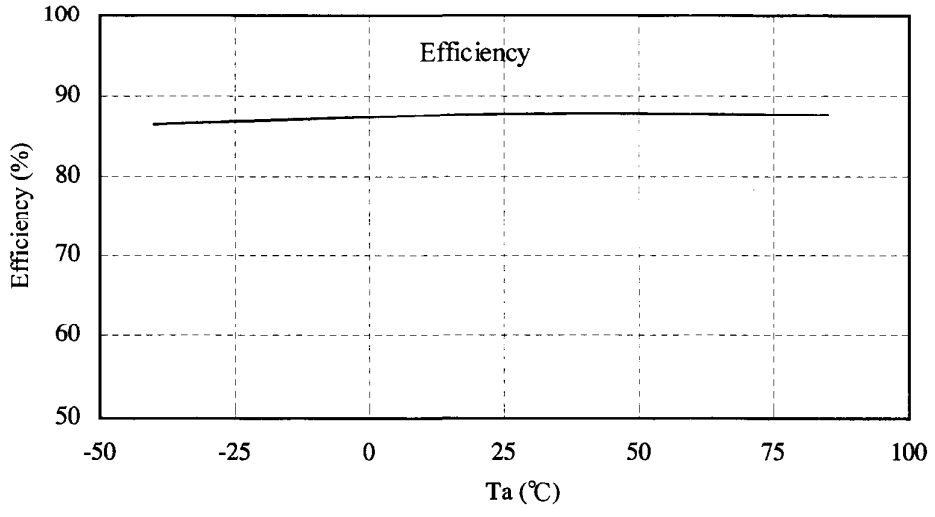
2. 1 (5) 効率対周囲温度
Efficiency vs ambient temperature

Conditions Vin : 48 VDC
Iout : 100 %
Air Velocity : 2 m/s

2.5V



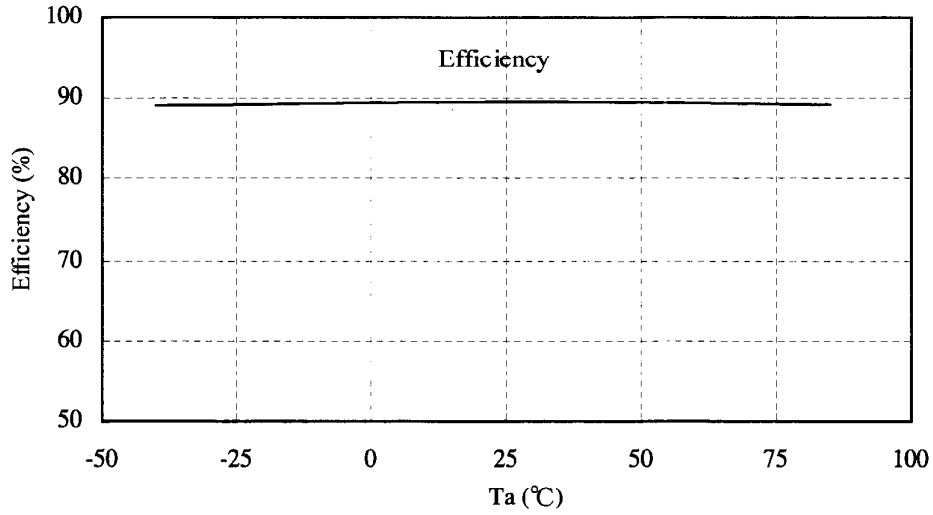
3.3V



2.1 (5) 効率対周囲温度
Efficiency vs ambient temperature

Conditions Vin : 48 VDC
Iout : 100 %
Air Velocity : 2 m/s

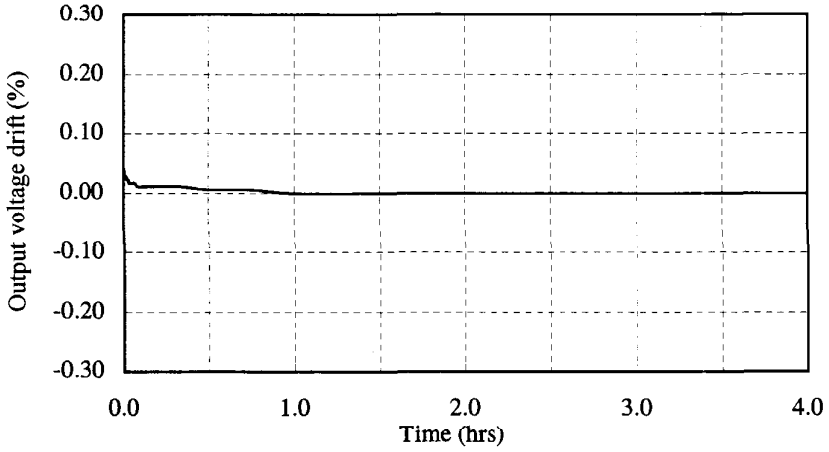
5V



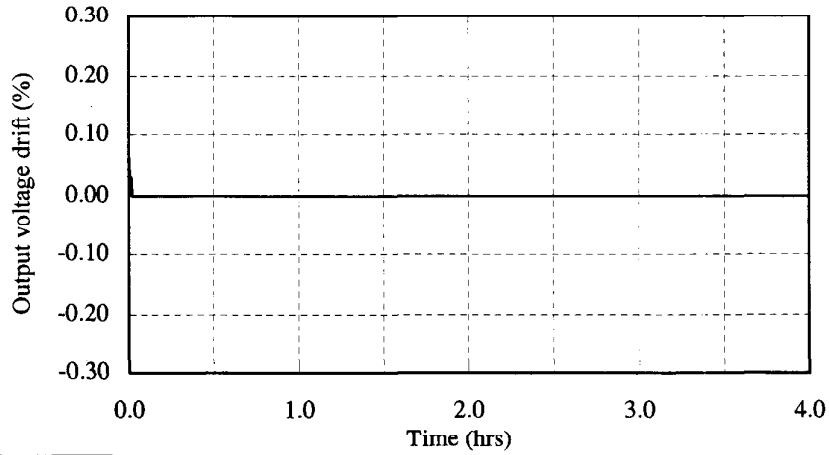
2. 2 通電ドリフト特性
Warm up voltage drift characteristics

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃
Air Velocity : 2 m/s

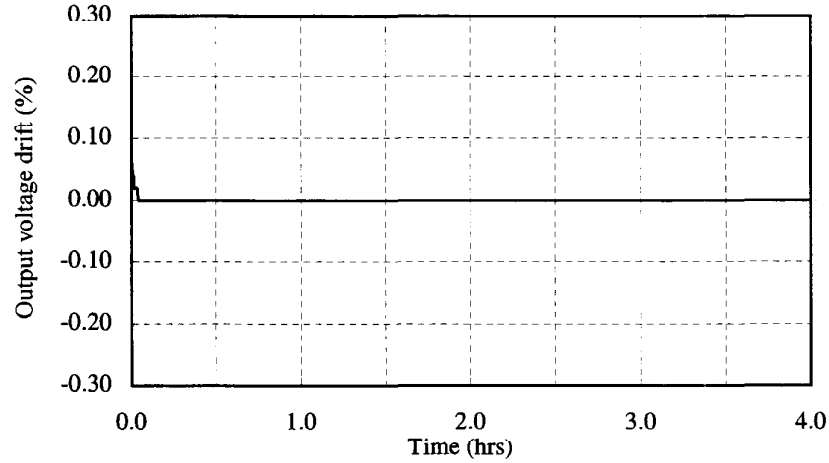
1.8V



3.3V



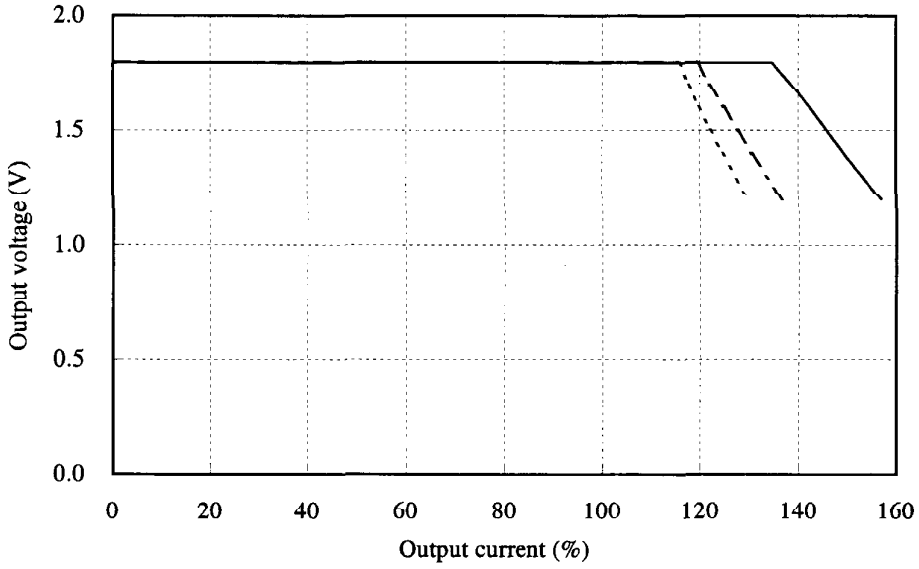
5V



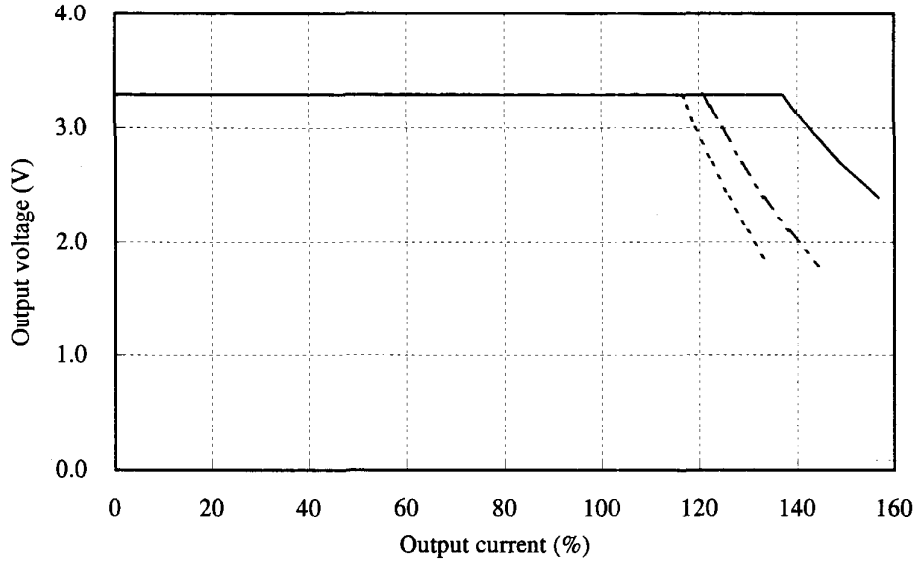
2. 3 過電流保護特性
Over current protection (OCP) characteristics

Conditions Vin : 36 VDC -------
: 48 VDC -.-.-.-
: 76 VDC ———
Ta : 25 ℃

1.8V



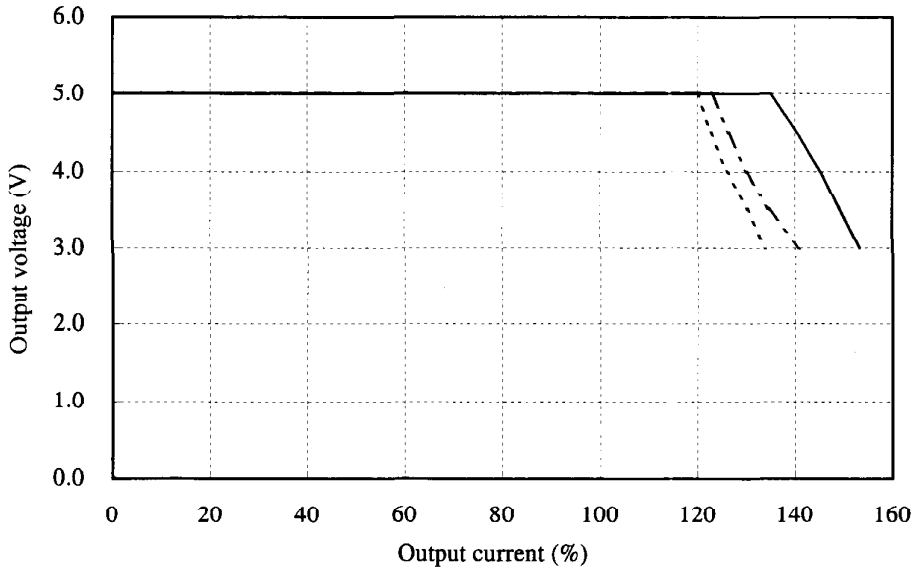
3.3V



2.3 過電流保護特性
Over current protection (OCP) characteristics

Conditions Vin : 36 VDC -------
: 48 VDC -·-·-·-·-
: 76 VDC ———
Ta : 25 ℃

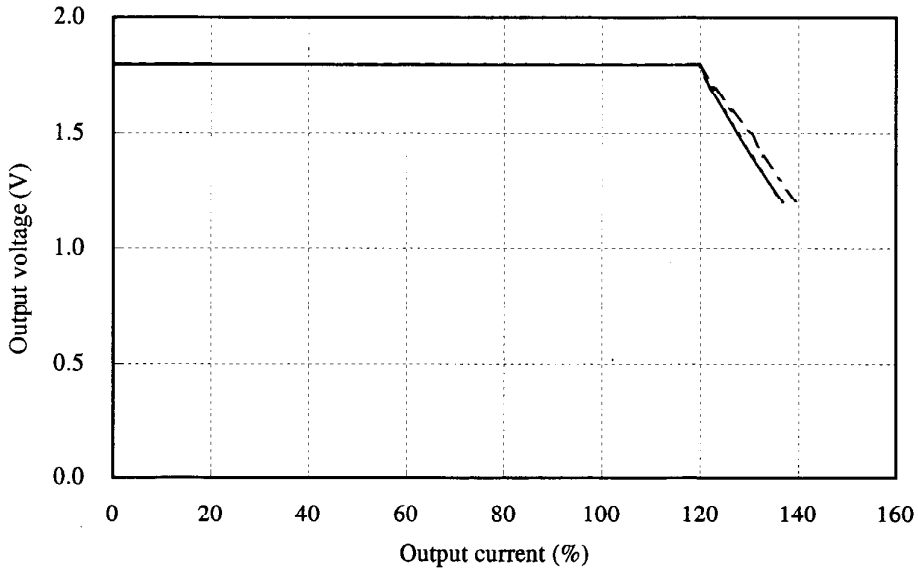
5V



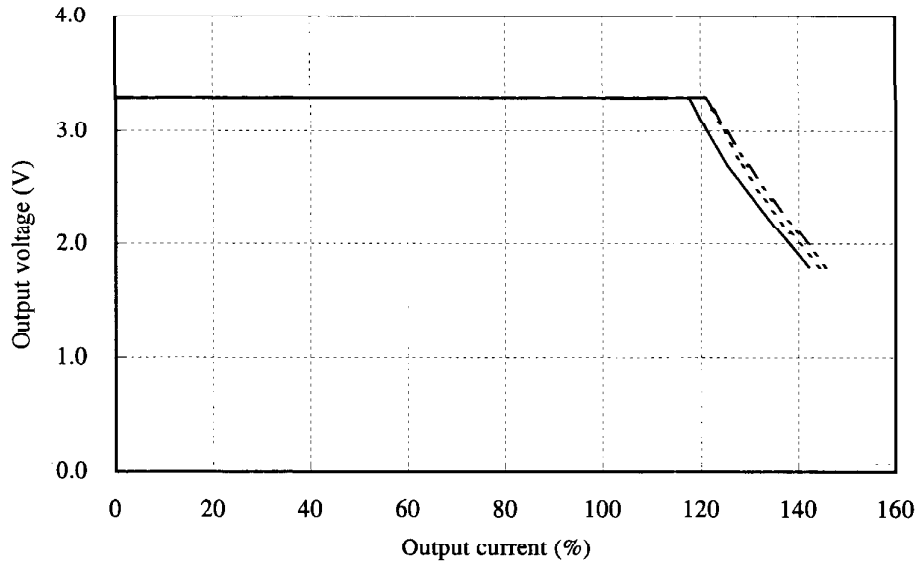
2. 3 過電流保護特性
Over current protection (OCP) characteristics

Conditions Ta : -40 ℃ -------
: 25 ℃ -.-.-.-
: 85 ℃ ———
Vin : 48 VDC

1.8V



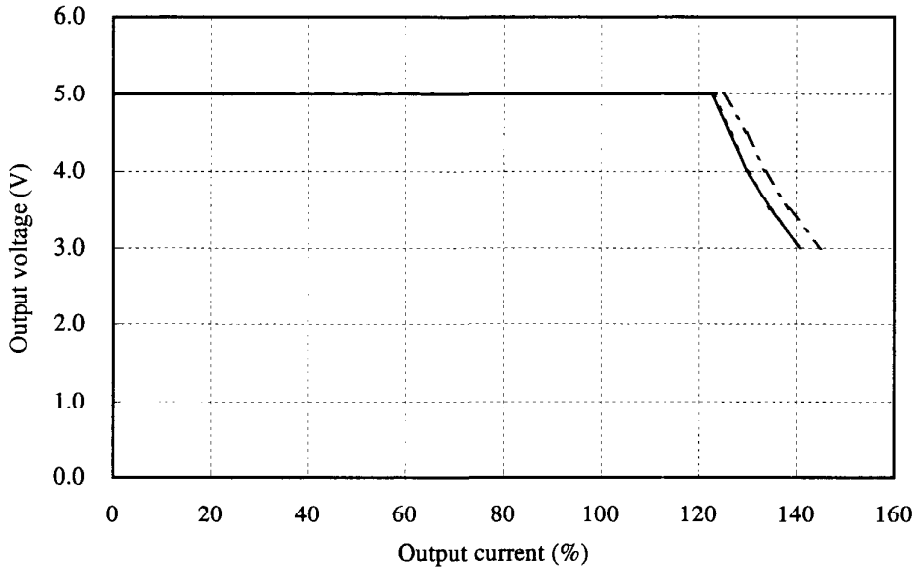
3.3V



2. 3 過電流保護特性
Over current protection (OCP) characteristics

Conditions Ta : -40 ℃ -------
: 25 ℃ -·-·-·-
: 85 ℃ ———
Vin : 48 VDC

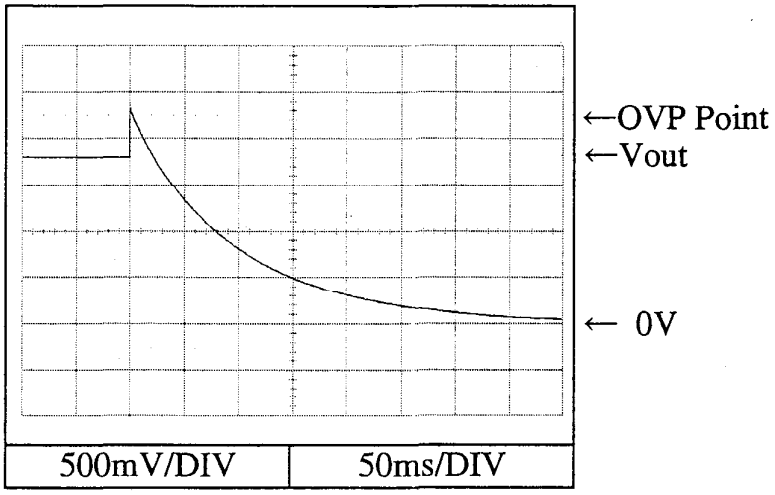
5V



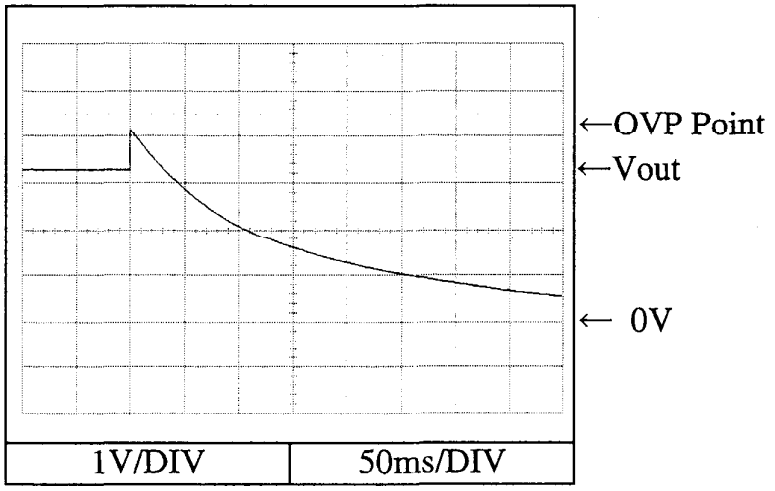
2.4 過電圧保護特性
Over voltage protection (OVP) characteristics

Conditions Vin : 48 VDC
Iout : 0 %
Ta : 25 ℃

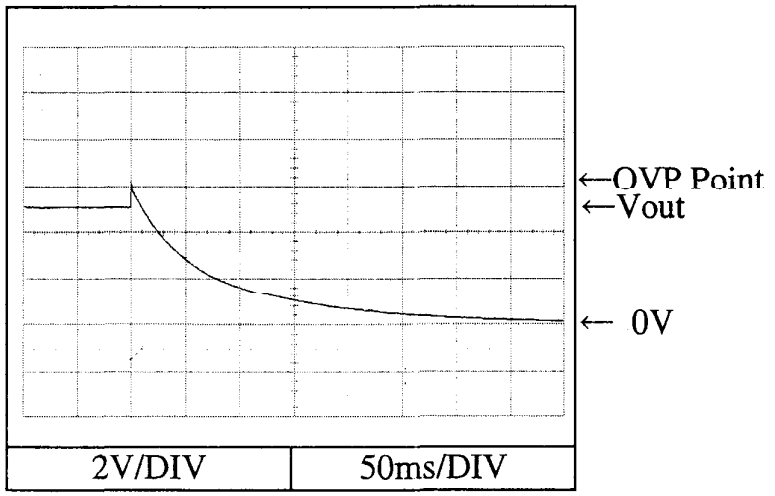
1.8V



3.3V

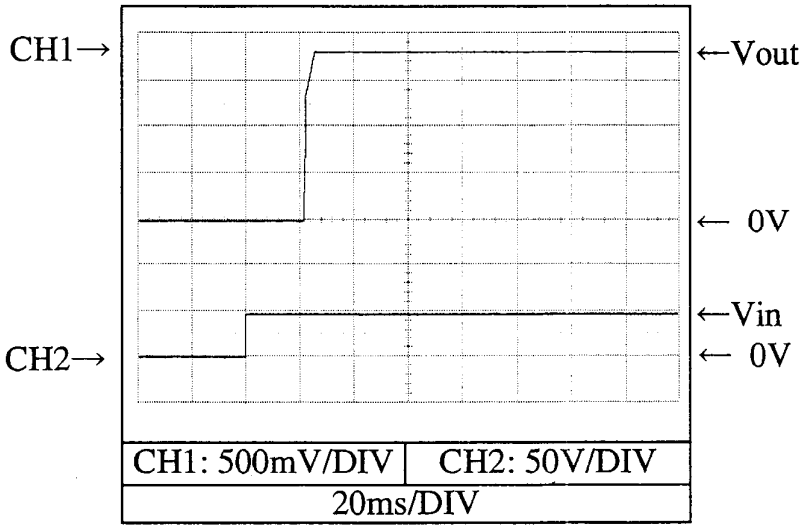


5V

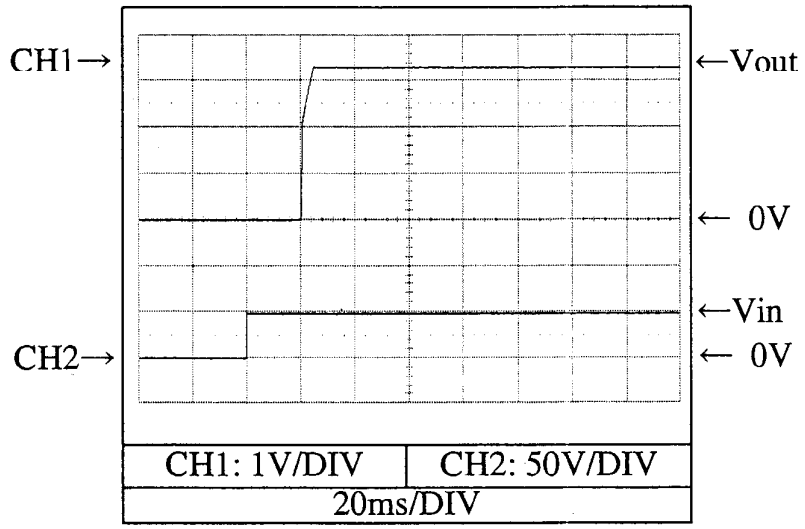


Conditions Vin : 48 VDC
Iout : 0 %
Ta : 25 ℃

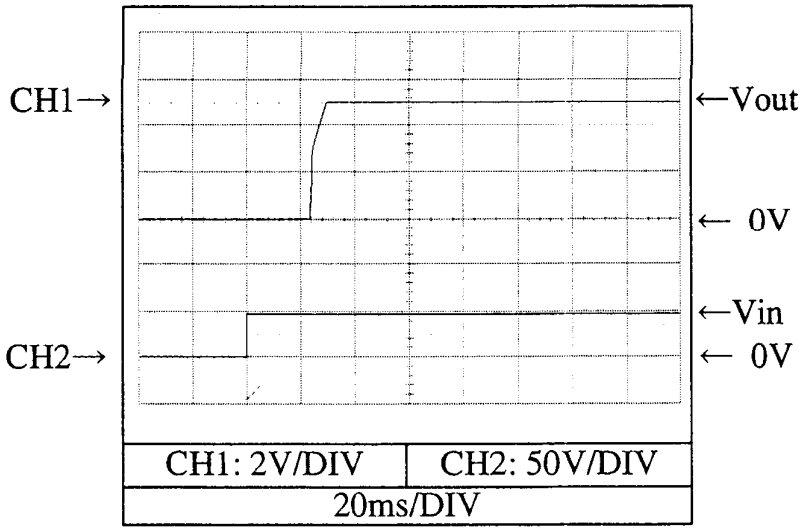
1.8V



3.3V



5V

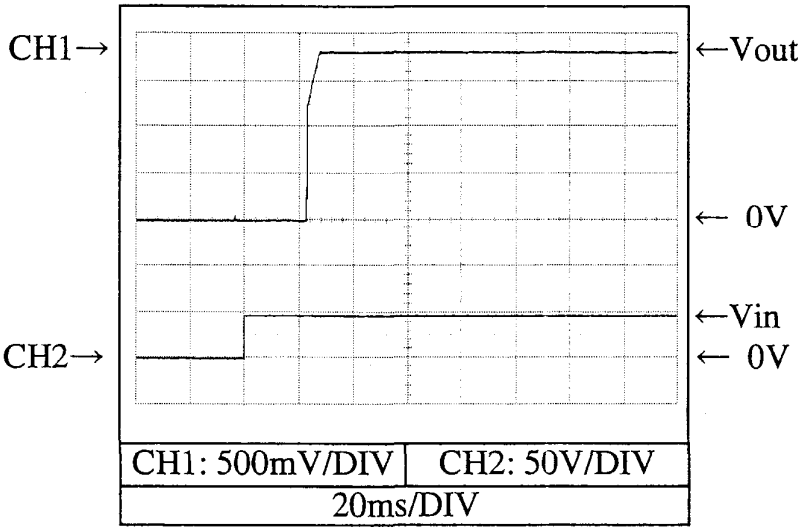


出力立ち上がり特性
Output rise characteristics

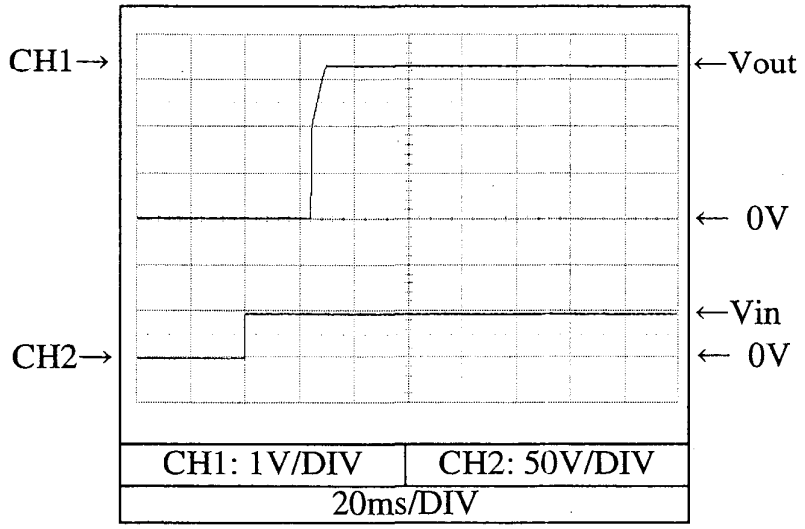
PAQ50S48-*

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

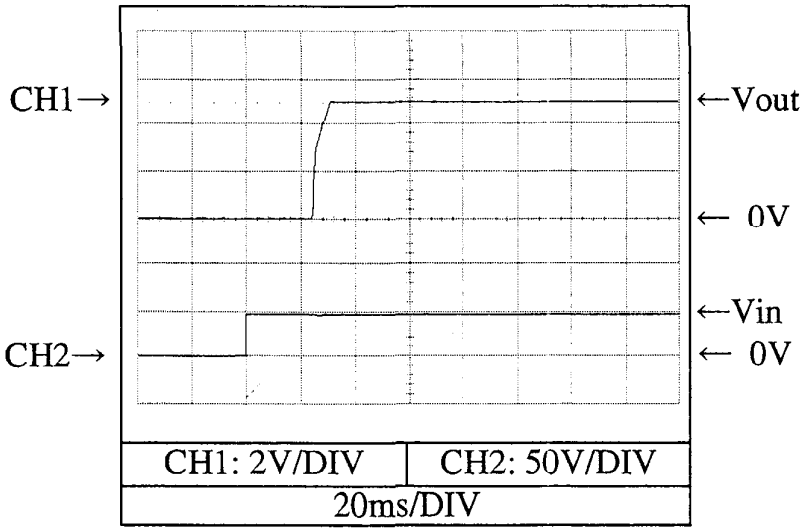
1.8V



3.3V

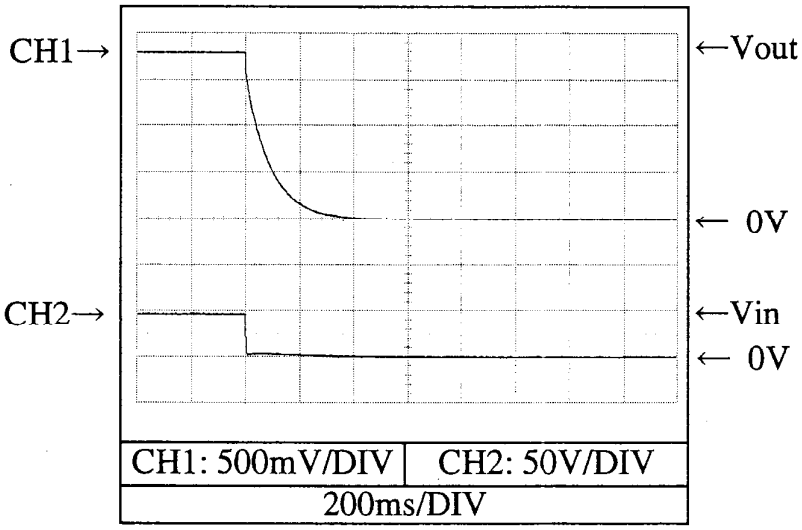


5V

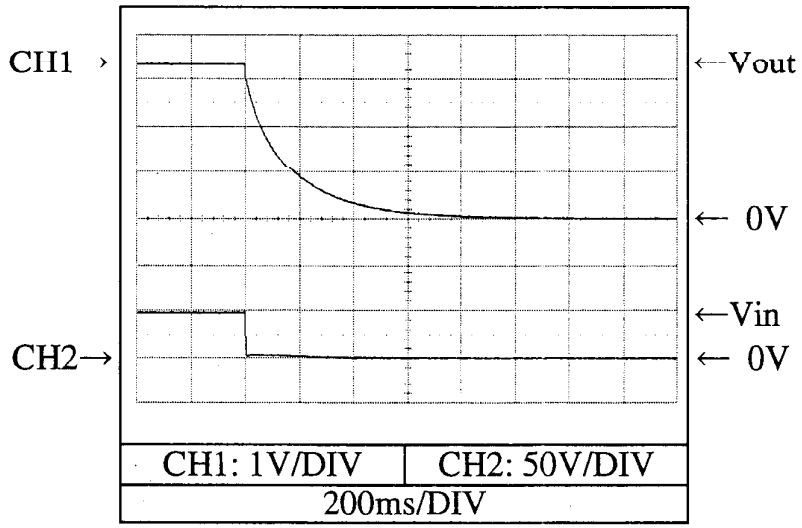


Conditions Vin : 48 VDC
Iout : 0 %
Ta : 25 ℃

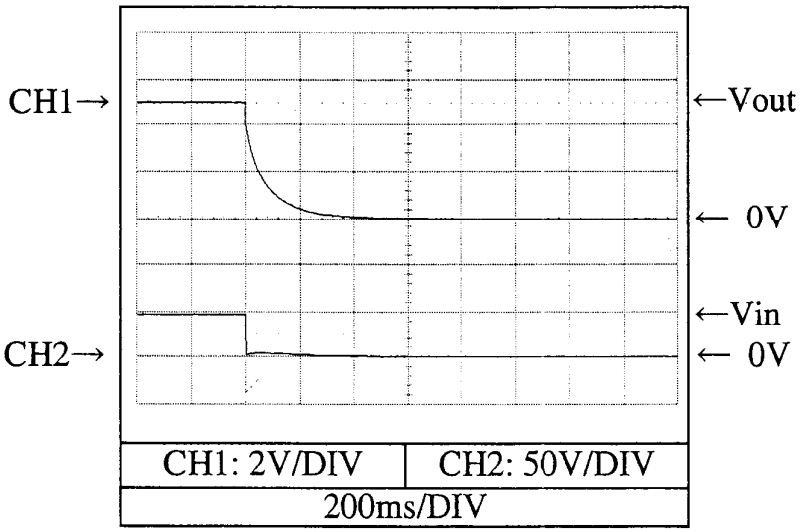
1.8V



3.3V



5V

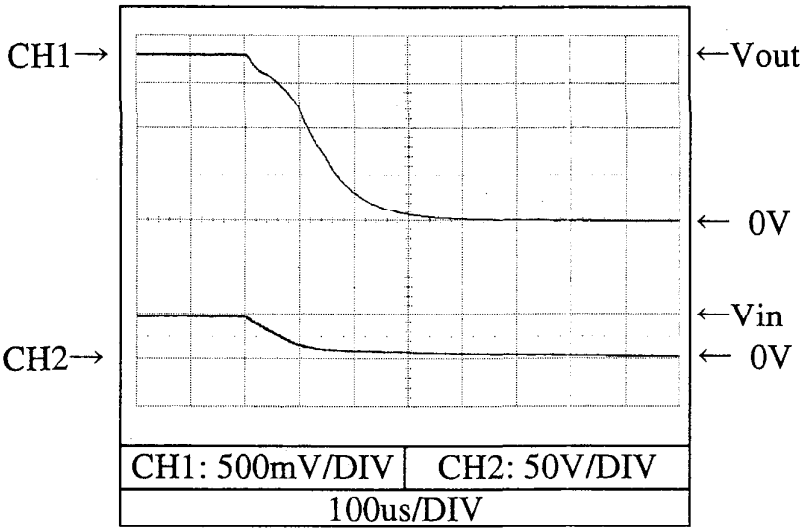


出力立ち下がり特性
Output fall characteristics

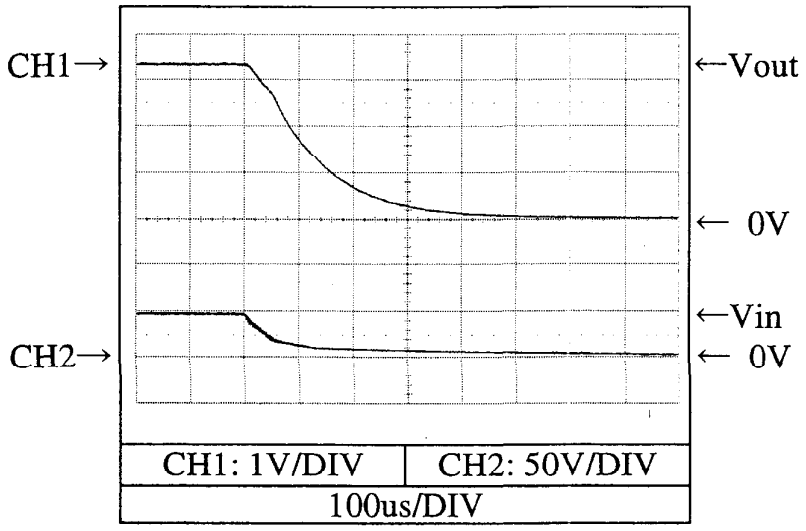
PAQ50S48-*

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

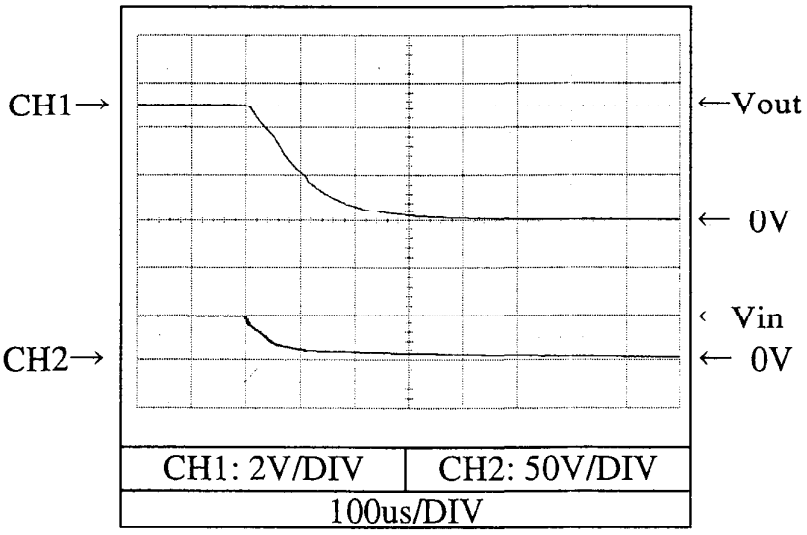
1.8V



3.3V

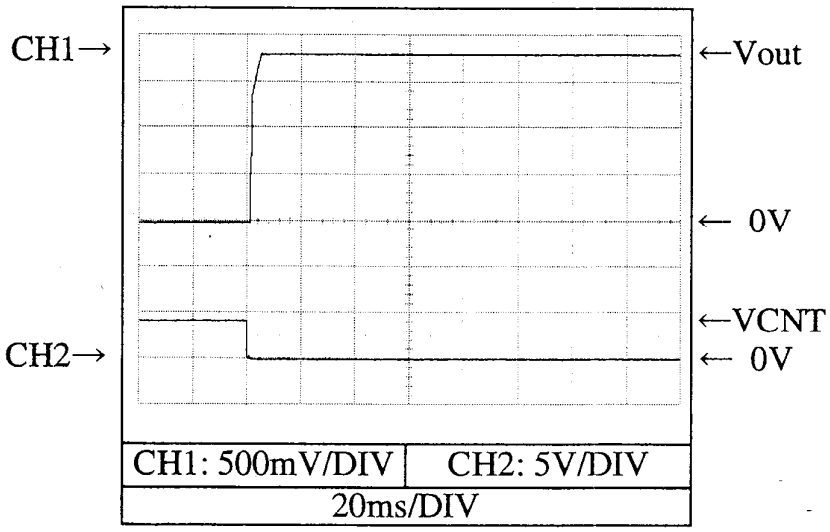


5V

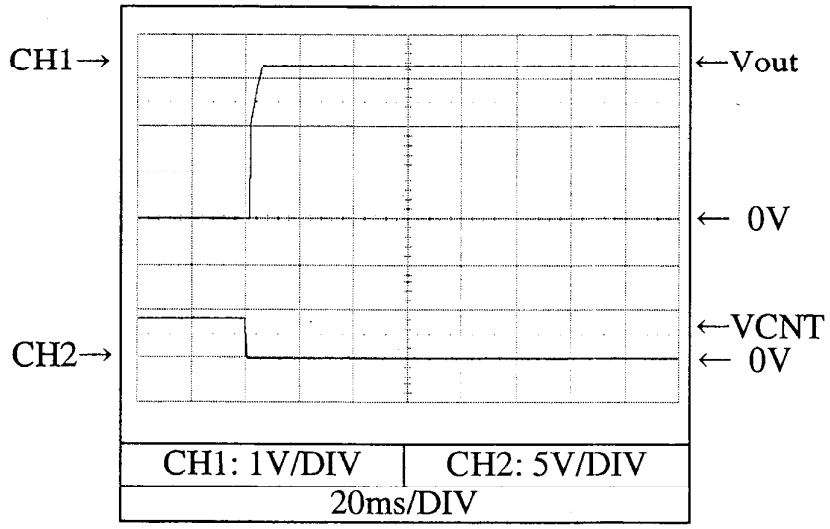


Conditions Vin : 48 VDC
Iout : 0 %
Ta : 25 ℃

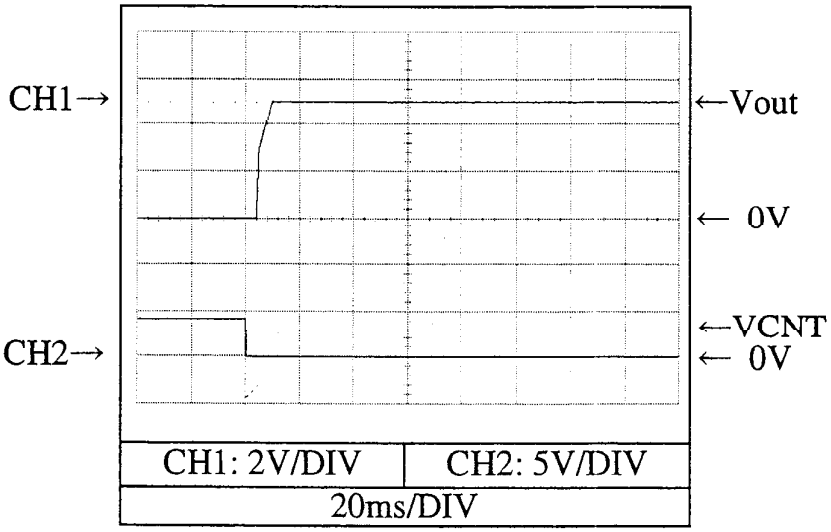
1.8V



3.3V



5V

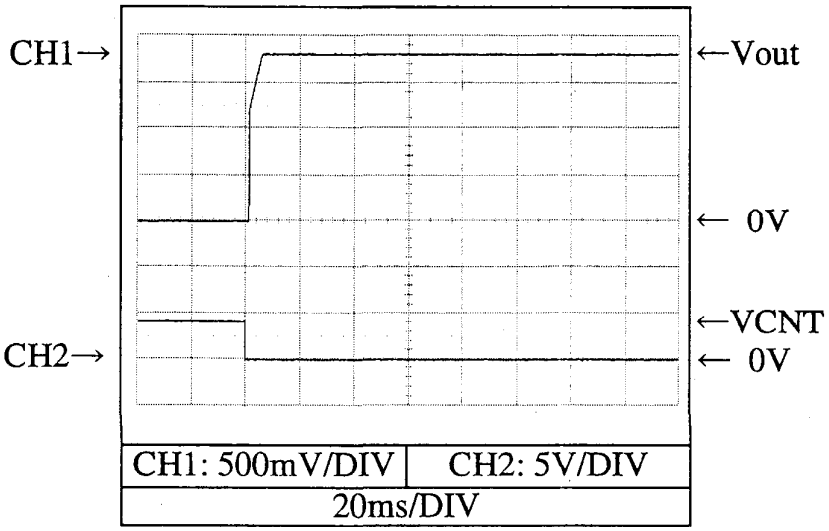


出力立ち上がり特性　（ＯＮ／ＯＦＦコントロール時）
Output rise characteristics with ON/OFF CONTROL

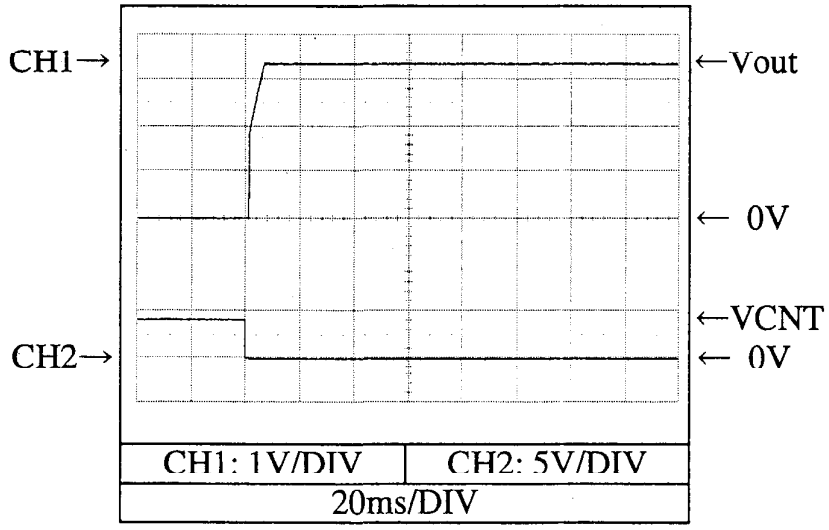
PAQ50S48-*

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

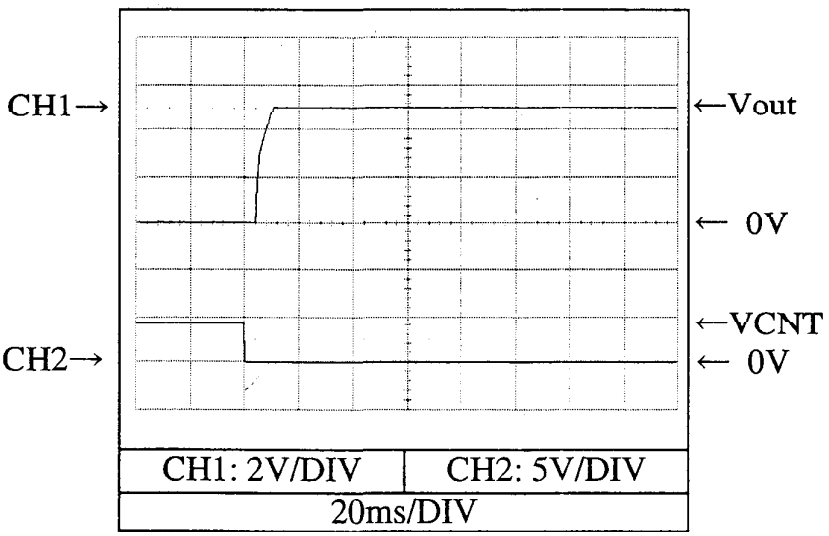
1.8V



3.3V

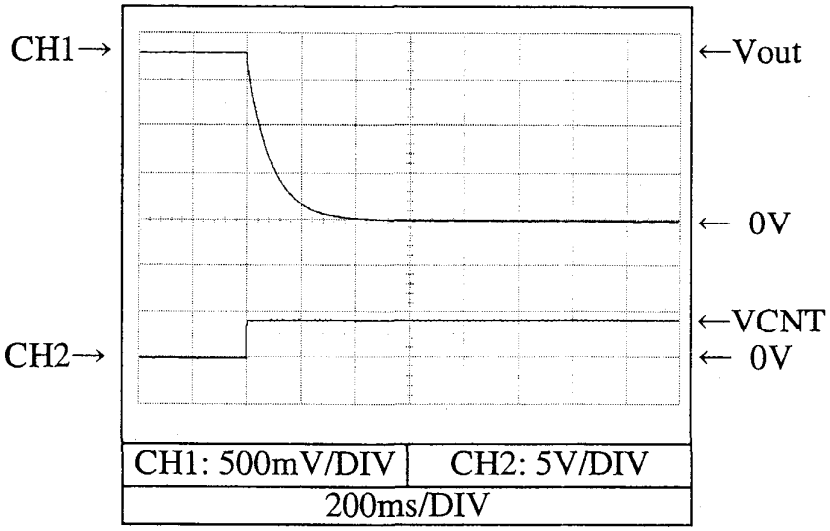


5V

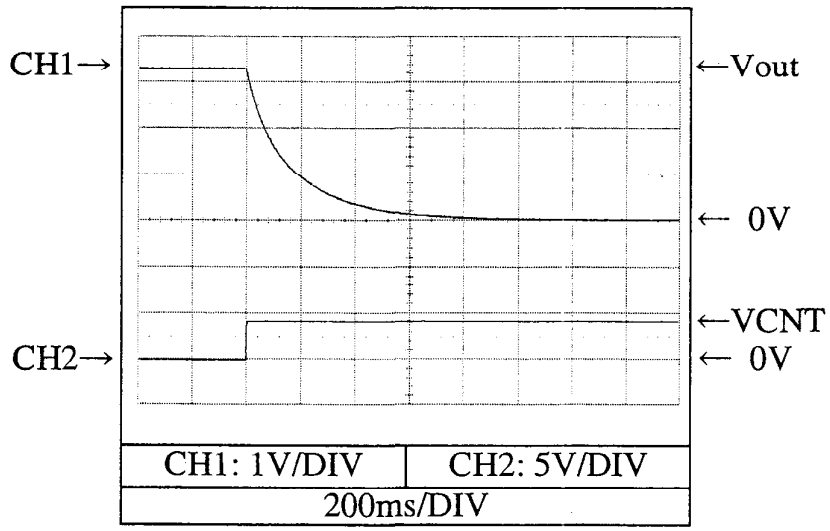


Conditions Vin : 48 VDC
Iout : 0 %
Ta : 25 ℃

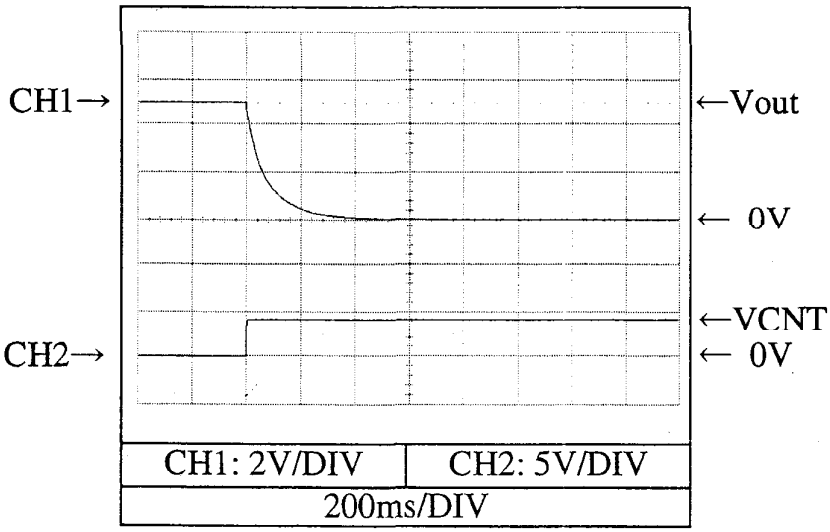
1.8V



3.3V



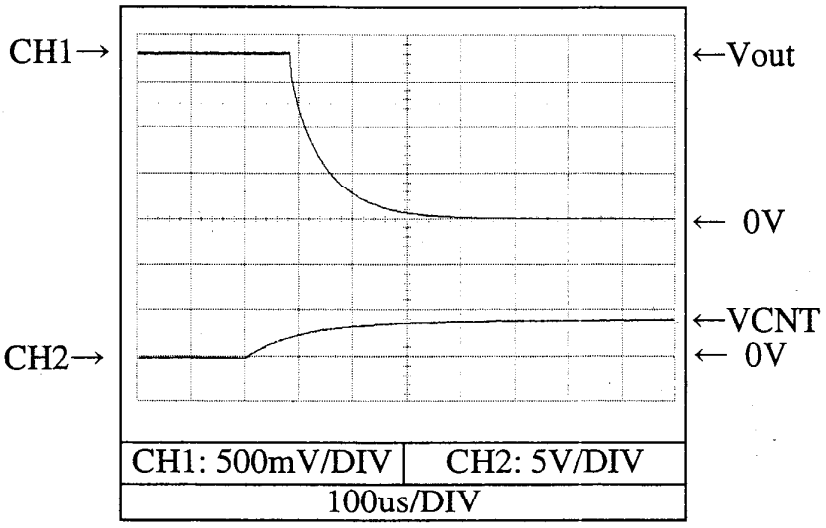
5V



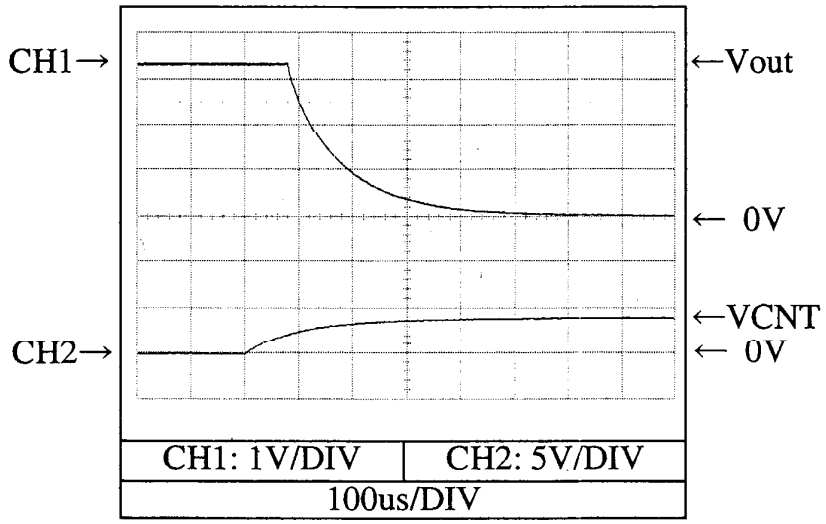
出力立ち下がり特性　（ＯＮ／ＯＦＦコントロール時）
Output fall characteristics with ON/OFF CONTROL

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

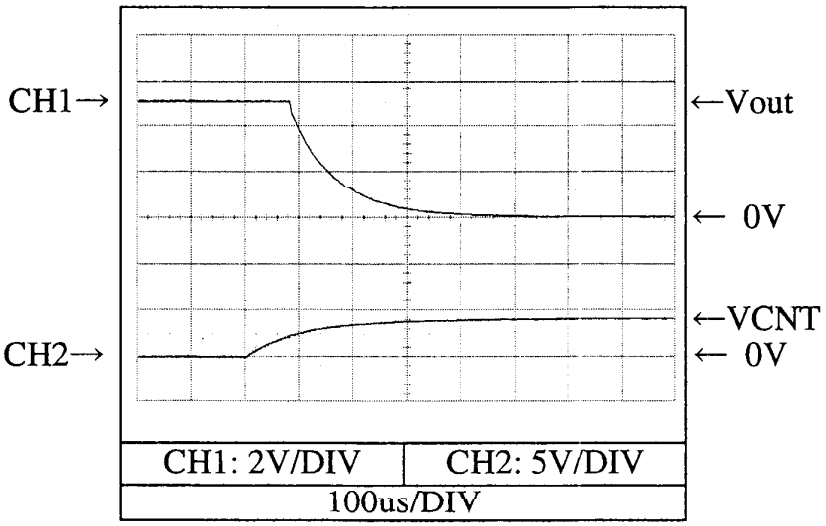
1.8V



3.3V



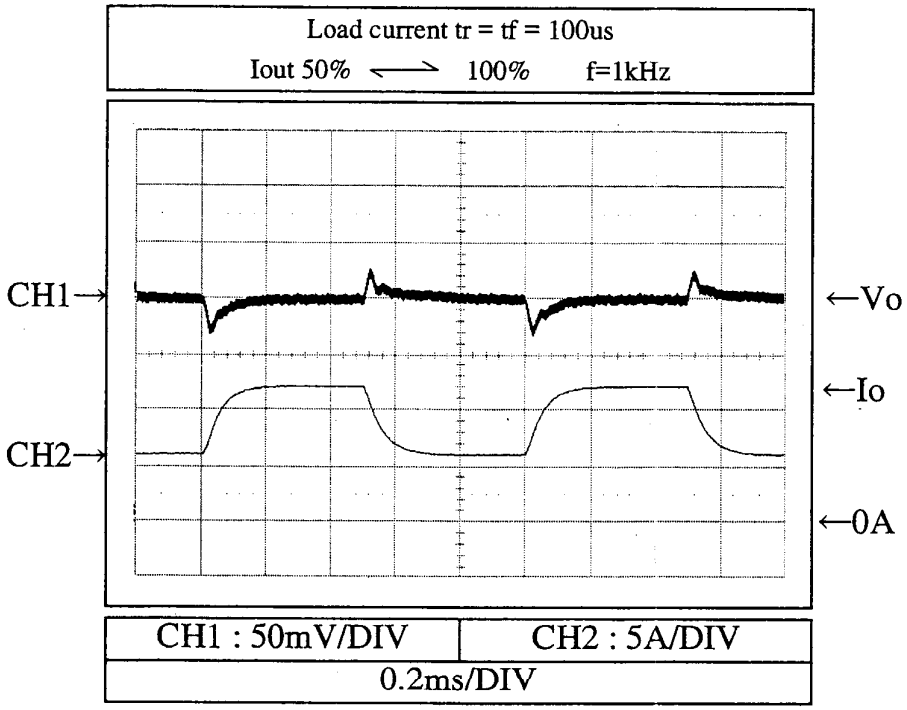
5V



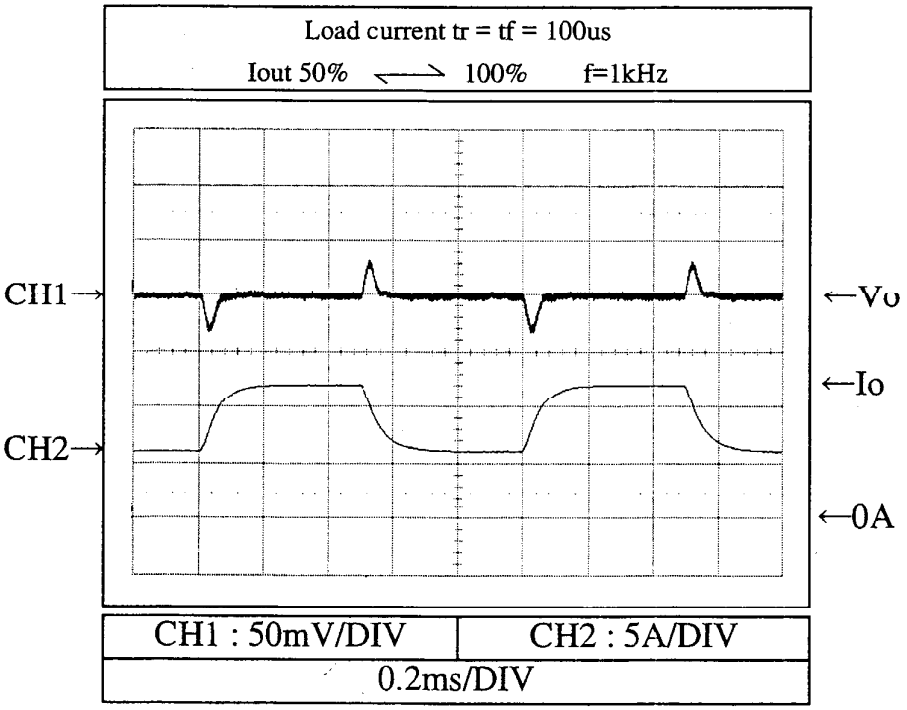
2. 9 過渡応答（負荷急変）特性
Dynamic load response characteristics

Conditions Vin : 48 VDC
Ta : 25 ℃

1.8V



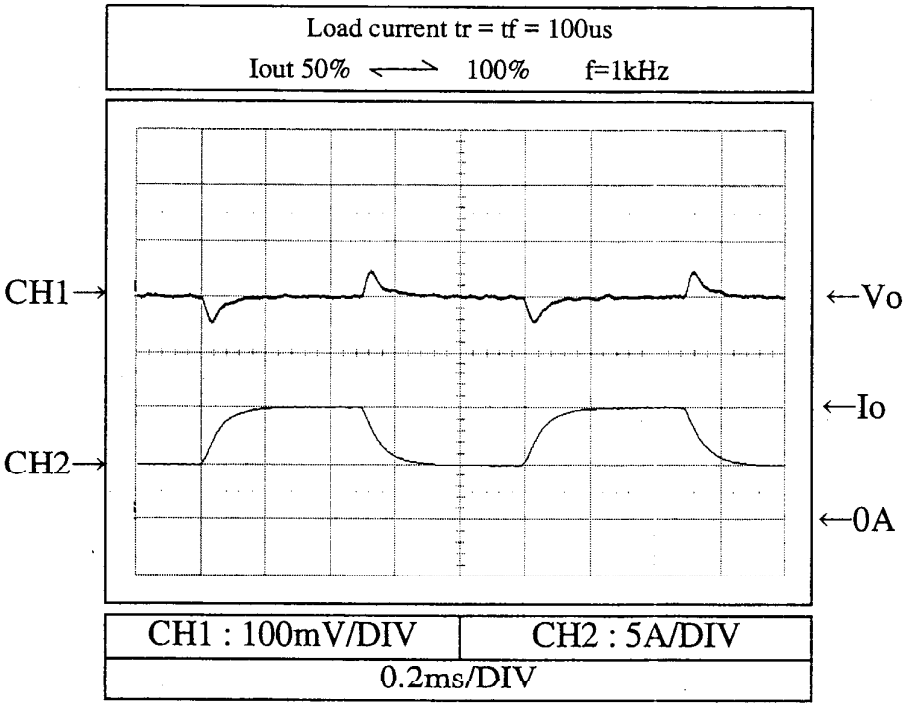
3.3V



2.9 過渡応答（負荷急変）特性
Dynamic load response characteristics

Conditions Vin : 48 VDC
Ta : 25 ℃

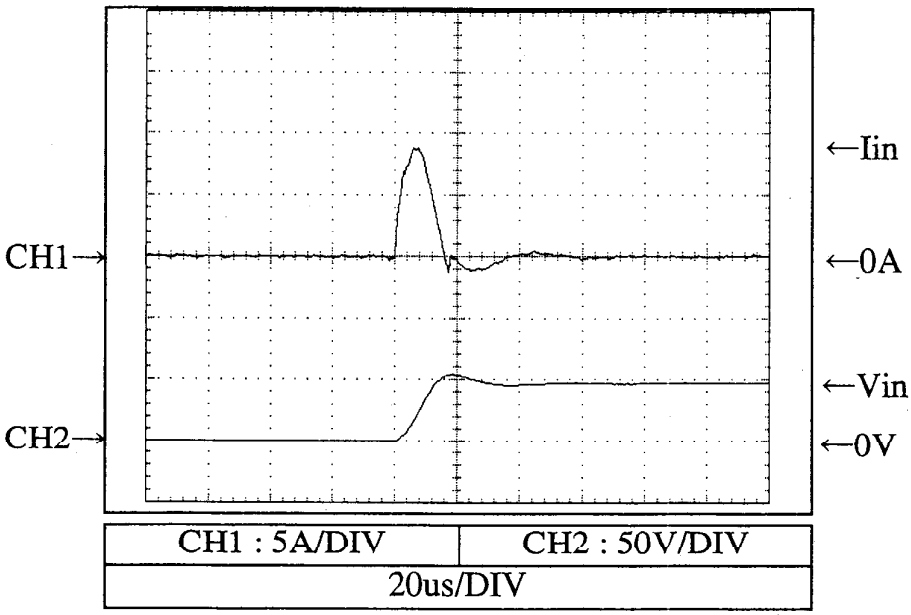
5V



2. 10 入力サージ電流（突入電流）特性
Inrush current waveform

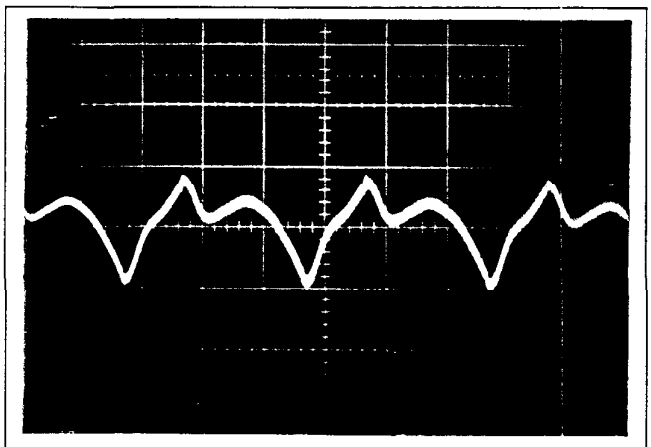
Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

3.3V



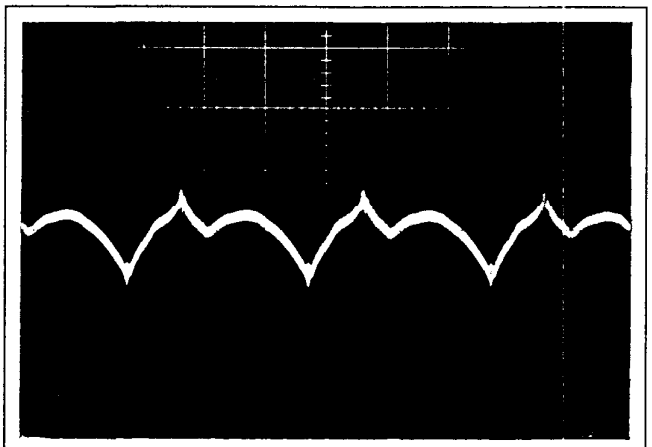
Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

1.8V



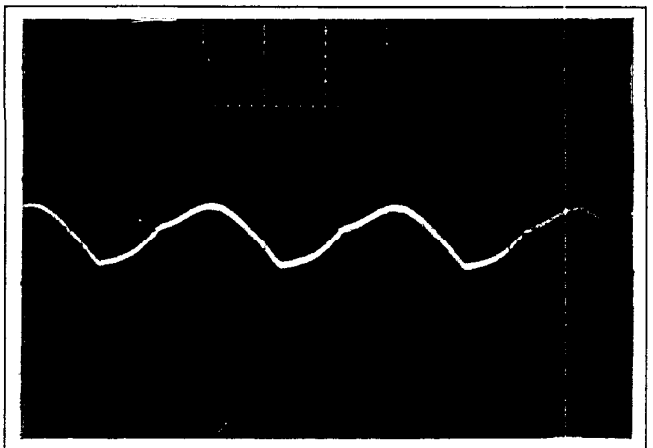
20mV/DIV	1 μ s/DIV
41.6mV	

3.3V



20mV/DIV	1 μ s/DIV
39.0mV	

5V



50mV/DIV	1 μ s/DIV
64.0mV	

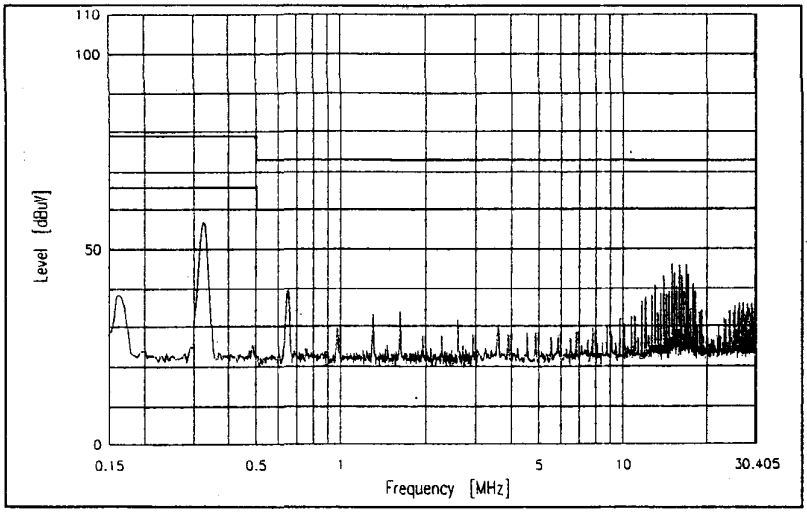
2.12 EMI特性
Electro-Magnetic Interference characteristics

(a) 雑音端子電圧（帰還ノイズ）
Conducted Emission

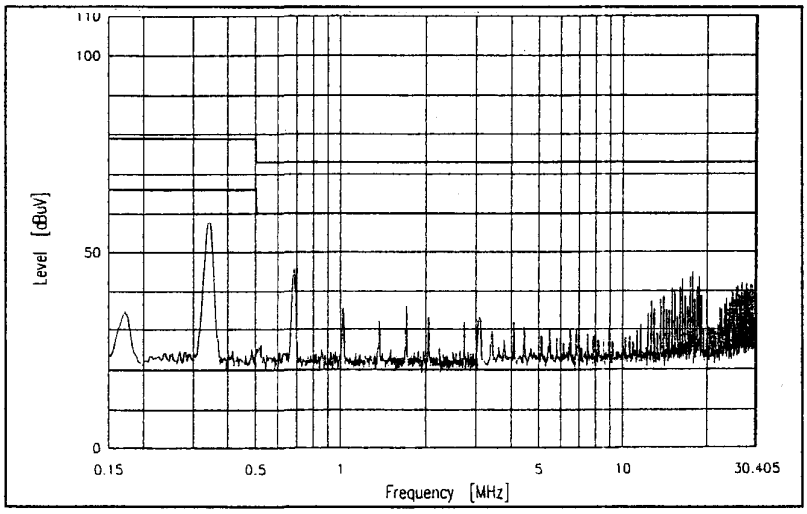
(1) VCCI class A 対応アプリケーションシステム
VCCI class A application system

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

1.8V



3.3V



EMI特性

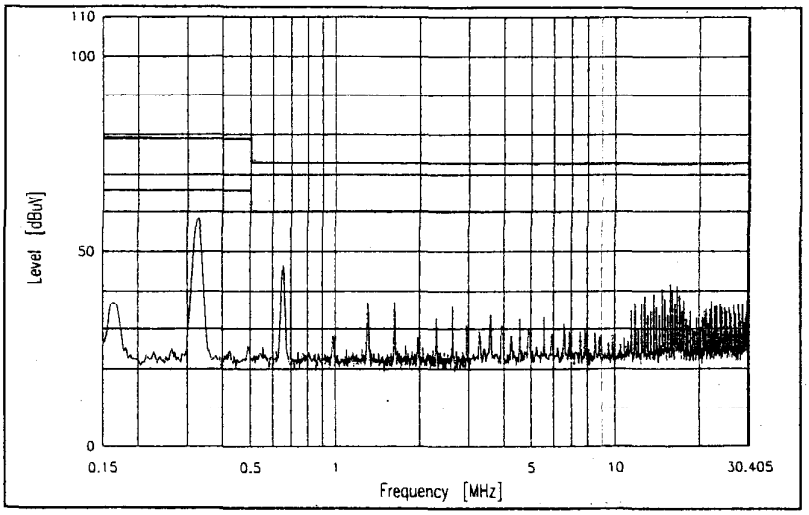
Electro-Magnetic Interference characteristics

(a) 雑音端子電圧（帰還ノイズ）
Conducted Emission

(1) VCCI class A 対応アプリケーションシステム
VCCI class A application system

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

5V



EMI特性

Electro-Magnetic Interference characteristics

(b) 雑音電界強度（輻射ノイズ）

Radiated Emission

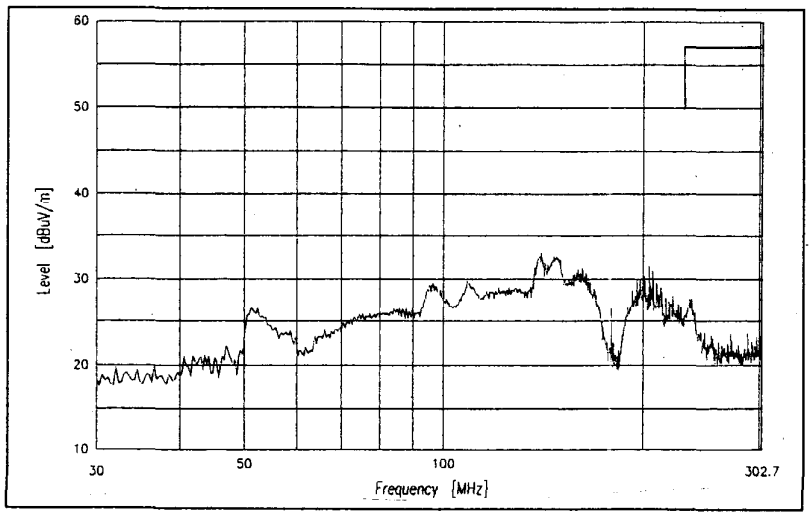
(1) VCCI class A 対応アプリケーションシステム

VCCI class A application system

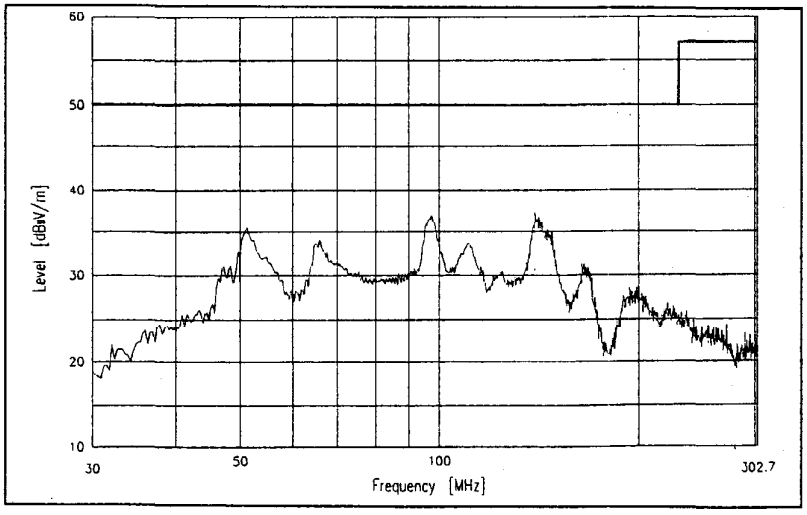
Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

1.8V

HORIZONTAL:



VERTICAL:



EMI特性

Electro-Magnetic Interference characteristics

(b) 雑音電界強度（輻射ノイズ）

Radiated Emission

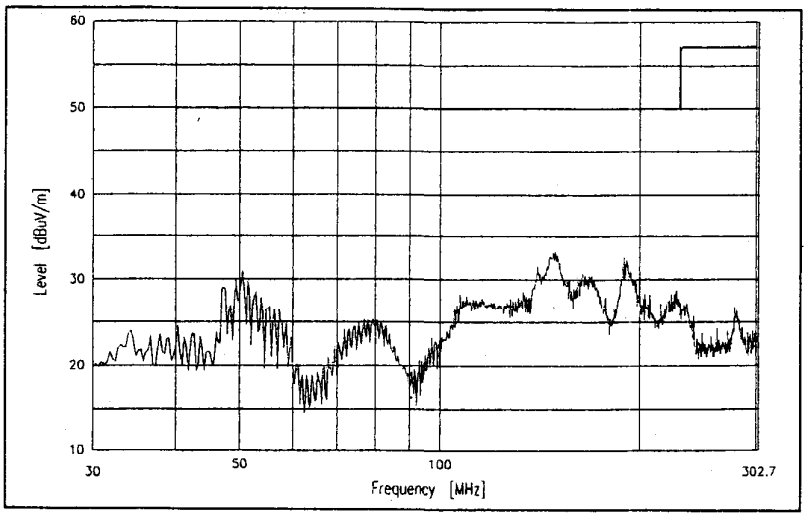
(1) VCCI class A 対応アプリケーションシステム

VCCI class A application system

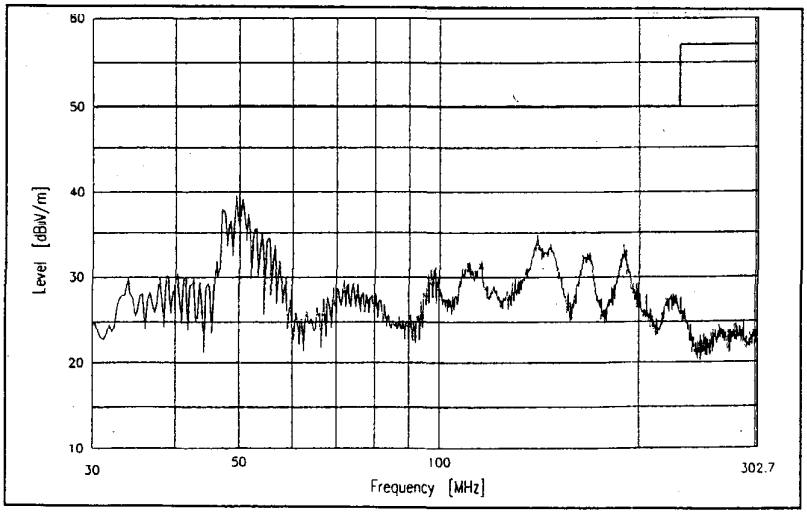
Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

3.3V

HORIZONTAL:



VERTICAL:



EMI特性

Electro-Magnetic Interference characteristics

(b) 雑音電界強度（輻射ノイズ）

Radiated Emission

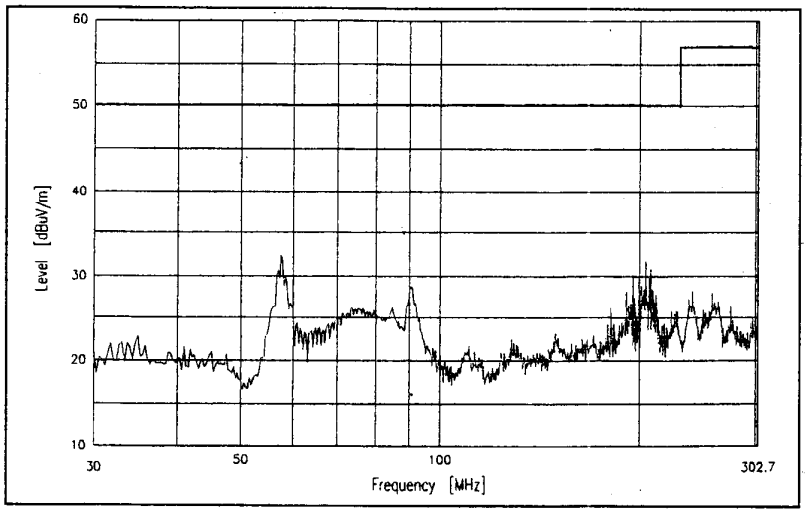
(1) VCCI class A 対応アプリケーションシステム

VCCI class A application system

Conditions Vin : 48 VDC
Iout : 100 %
Ta : 25 ℃

5V

HORIZONTAL:



VERTICAL: